Advances in designs and mechanisms of semiconducting metal oxide nanostructures for high-precision gas sensors operated at room-temperature

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Abstract

High-precision gas sensors operated at room temperature are attractive for various real-time gas monitoring applications, with advantages including low energy consumption, cost effectiveness and device miniaturization/flexibility. Sensing materials, which play a key role for the good gas sensing performance, are currently focused extensively on semiconducting metal oxide nanostructures (SMONs) used in the conventional resistance type gas sensors. This topical review highlights the designs and mechanisms of different SMONs with various patterns (e.g. nanoparticles, nanowires, nanosheets, nanorods, nanotubes, nanofilms, etc.) for gas sensors to detect various hazardous gases at the room temperature. The key topics include: (1) single phase SMONs including both n-type and p-type ones; (2) noble metal nanoparticles and metal ion modified SMONs; (3) composite oxides of SMONs; (4) composites of SMONs with carbon nanomaterials. Enhancement of sensing performance of the SMONs at the room temperature can also be enhanced using photo-activation effect such as ultraviolet light. The SMON based mechanically flexible and wearable room temperature gas sensors are also discussed. Various mechanisms have been discussed for the enhanced sensing performance, which include redox reactions, heterojunction generation, formation of metal sulfides and spillover effect. Finally, major challenges and prospects for the SMONs based room temperature gas sensors are highlighted.

Key words: Semiconducting metal oxide; Nanostructure; Gas sensor; Hazardous gas; Sensing mechanism; Sensing performance.
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Acknowledgements
References
1. Introduction

Various types of hazardous gases, such as H$_2$S, CO, NO$_2$, NH$_3$, H$_2$, CH$_4$, toluene, acetone, ethanol, methanol and benzene, are routinely and daily released from industrial and agriculture processes, or emitted as vehicle exhaust emissions. Some of them, such as H$_2$ and CH$_4$, are explosive when exposed to air, whereas the others, such as NO$_2$ and toluene, are harmful for human health and environment, when their concentrations are above a critical threshold, sometimes as low as in parts-per-million (ppm) levels. Therefore, development of high-precision gas sensors with high sensitivity, fast response, good selectivity, low limit of detection (LOD), as well as in-situ and real-time monitoring capabilities is paramount $^{1,2}$. For this purpose, various types of gas sensors have been developed, mainly including resistive $^{3-5}$, optical $^{6-9}$, ultrasonic and acoustic wave $^{10-12}$, thermoelectric $^{13,14}$ and electrochemical $^{15-17}$ ones.

![Fig. 1. Schematic diagram of resistance-type gas sensors based on semiconducting metal oxide nanostructures for detection of various hazardous gases.](image-url)

Among these gas sensors, the resistive gas sensor is one of the most popular types, and is simple and easy to be fabricated using cost effective processes. The transduction mechanism of resistive gas sensors is based on the change in resistance of a sensing layer upon adsorption and reaction with the target gas molecules. The sensing layer usually determines the sensitivity and selectivity. Therefore, the sensing materials and the structures of the sensing layer are highly critical to their sensing performance. The
sensing materials used in these resistive gas sensors are mainly semiconducting metal oxide nanostructures (SMONs) \(^{18-21}\), carbon materials \(^{22-26}\) and organic semiconductors \(^{27-30}\). Compared to the carbon materials and organic semiconductors, the SMONs generally have higher sensitivity, quicker response/recovery speed, better reversibility and stability, and they are cost-effective with simple fabrication processes \(^{18-20}\). The SMONs have large specific surface areas with numerous active sites, which facilitate fast adsorption and reaction of target gases, thus enhancing their sensing performance. They have been used to detect various hazardous gases for different applications as shown in Fig. 1. These SMON sensing materials mainly include ZnO \(^{31, 32}\), CuO \(^{33-36}\), SnO\(_2\) \(^{37-39}\), TiO\(_2\) \(^{40, 41}\), Fe\(_2\)O\(_3\) \(^{42, 43}\), In\(_2\)O\(_3\) \(^{44-47}\), Co\(_3\)O\(_4\) \(^{48-50}\) and WO\(_3\) \(^{18, 51}\). For further improvement of sensing performance, they have been modified using noble metals \(^{52-55}\), metal ions \(^{56-60}\), and carbon materials \(^{61-64}\). Composites of multi-phase SMONs \(^{65-67}\) have also been frequently reported.

SMONs-based sensors are usually heated to a higher temperature (between 100 °C to 400 °C) for performance enhancement at the expense of structural complications \(^{42-47}\). Operation at elevated temperature levels significantly increases the energy-consumption, overall device size and cost of gas sensors. Heating up to a high temperature could lead to changes of microstructure of the sensing nanomaterials, which can result in degradation of sensing performance. In addition, high-temperature sensing has its practical limitations. Particularly, heating is very dangerous for the detection of flammable and explosive gases, with a risk of explosion. Therefore, sensors operated at room temperature (RT) are desirable for minimizing energy consumption and cost, increasing security and stability, realizing device miniaturization and suitability for handheld operations \(^{68, 69}\). For these reasons, RT gas sensors based on the SMONs receive extensive attention in recent years. Different configurations of SMONs employing nanostructures have been demonstrated with desirable performance enhancements \(^{70}\), regarding to sensitivity, response/recovery time, selectivity, reversibility, reproducibility and long-term stability. Various MSONs have been designed and synthesized, such as nanorods \(^{71-75}\), nanoparticles \(^{76-81}\), nanowires \(^{82-89}\), nanospheres \(^{90}\), nanosheets \(^{91-94}\), nanotubes \(^{95-98}\), and mesoporous nanostructures \(^{99-103}\).
The literature in SNOM-based RT gas sensing is rich and the application area is very critical. New devices have been regularly introduced. Although the merits of the SMONs based RT gas sensors have already been demonstrated, currently there are still some key challenges:

(1) The sensing performance of these SMON based gas sensors is limited, when operated at RT. For example, many of these sensors exhibit insufficient sensitivities $10^4$-$10^8$.

(2) The response/recovery times of many RT gas sensors, which are crucial for rapid detection of target dangerous gases to timely trigger an alarm, are generally quite long, sometimes, up to tens of minutes $10^9$-$11^1$.

(3) Poor reversibility has been reported for some of these sensors operated at RT $10^1$.

(4) Poor selectivity is another key limitation for the RT gas sensors. Selectivity of many SMON based RT gas sensors needs to be improved to avoid interference and cross-talks $112$.

The aim of this topical review is to critically evaluate the design and structure of SMONs-based gas sensors that may help guide the design of new devices. The performance of these SMONs based gas sensors operated at RT could be improved significantly by modifying the SMONs using noble metal nanoparticles $113$-$116$, metal ions $117$-$119$, composites of multiple-SMON $120$-$123$ and carbon nanomaterials $124$-$126$. In addition, not only the quantity of chemisorbed oxygen species $127$, defects $128$ and element compositions $129$, $130$ on the surface of SMONs, but also the structural properties, i.e. porosity $131$, heterojunction properties $132$-$134$ and conductivity $135$, $136$ can affect the RT gas sensing performance. Therefore, understanding the relationship between sensing properties and structures of SMONs is crucial to design the gas sensing materials with the good sensing performance operated at RT.

Several review papers have been published on gas sensors based on the different SMON sensing materials, including n-type oxide semiconductors such as ZnO $20$, $137$, Fe$_2$O$_3$ $138$, SnO$_2$ $39$, $139$, $140$, p-type oxide semiconductors $141$, metal oxide-based heterojunctions $142$, noble metal/metal oxide semiconductors $143$, $144$ and graphene-metal oxide nanohybrids $145$. However, these review papers discuss the sensing properties of
the sensors which are generally operated at higher working temperatures above RT \(^{146-150}\). Others about the RT gas sensors are focused more on certain types of SMONs based on RT sensors, such as nanostructured ZnO based RT gas sensors \(^{151}\). However, there is no comprehensive review which is focused on the recent progress of various SMONs for high-precision gas sensors operated at RT. Therefore, this review will comprehensively summarize and discuss the recent developments of the RT gas sensors based on single phase SMONs, noble metal and metal ion modified SMONs, composites of SMONs with other metal oxides, and the composites of SMONs with carbon nanomaterials, as shown in the Fig. 2. In addition, we will discuss the effect of UV light stimulation to enhance the performance of SMONs based RT gas sensors, and mechanically flexible RT gas sensors based on the SMONs.

![Fig. 2. Schematic diagram of various semiconducting metal oxide nanostructures used for RT gas sensors presented in this review.](image)

2. Room temperature gas sensors based on single phase semiconducting metal oxide nanostructures
  
  2.1 N-type semiconducting metal oxide nanostructures and gas sensors
N-type SMONs are the most reported sensing materials for the RT resistive gas sensors, and they include ZnO, SnO2, In2O3, WO3, TiO2, Fe2O3, MoO3, VO2 and CeO2. Various forms of nanostructures including nanoparticles, nanorods, nanowires, nanoflowers, nanosheets, nanofilms, nanotubes, porous structures and hierarchical nanostructures have been employed to detect various types of gases including H2S, NO2, H2, NH3, acetone, alcohol, HCHO, liquefied petroleum gas (LPG), etc. Table 1 summarizes some of the reported RT sensors using the n-type SMONs.

Table 1 Summary of room temperature sensing properties of n-type semiconducting metal oxide nanostructures

<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>t_res/t_rec</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>ZnO</td>
<td>Combs</td>
<td>CVD</td>
<td>H2S</td>
<td>4</td>
<td>6</td>
<td>22/540 s</td>
<td>100 ppb</td>
<td>152</td>
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<tr>
<td>ZnO</td>
<td>Dendritic</td>
<td>Vapor-phase transport</td>
<td>H2S</td>
<td>500</td>
<td>26.4</td>
<td>20/50 s</td>
<td>10 ppm</td>
<td>153</td>
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<td>Nanorods</td>
<td>Hydrothermal</td>
<td>H2S</td>
<td>1</td>
<td>~35</td>
<td><del>20/</del> min</td>
<td>0.05 ppm</td>
<td>109</td>
</tr>
<tr>
<td>ZnO</td>
<td>quantum dots</td>
<td>Colloidal progress</td>
<td>H2S</td>
<td>50</td>
<td>113.5</td>
<td>16/820 s</td>
<td>10 ppm</td>
<td>177</td>
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<td>Nanorods</td>
<td>Vapor-phase transport</td>
<td>H2S</td>
<td>1</td>
<td>296</td>
<td>320/3592 s</td>
<td>0.5 ppm</td>
<td>71</td>
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<td>ZnO</td>
<td>Thin films</td>
<td>Thermal evaporation</td>
<td>Ethanol</td>
<td>100</td>
<td>3</td>
<td>-</td>
<td>-</td>
<td>178</td>
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<td>Tetrapod network</td>
<td>Thermal oxidation</td>
<td>Ethanol</td>
<td>1000</td>
<td>~4.5</td>
<td>300/~ s</td>
<td>~10 ppm</td>
<td>179</td>
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<td>Nanorods</td>
<td>Laser ablation</td>
<td>Ethanol</td>
<td>250</td>
<td>14</td>
<td>-</td>
<td>~1 ppm</td>
<td>154</td>
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<td>Nanorods</td>
<td>Electrospinning</td>
<td>Ethanol</td>
<td>100</td>
<td>23</td>
<td>26/43 s</td>
<td>~1 ppm</td>
<td>180</td>
</tr>
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<td>Nanowires</td>
<td>Electrospinning</td>
<td>Ethanol</td>
<td>100</td>
<td>78</td>
<td>9/12 s</td>
<td>~1 ppm</td>
<td>82</td>
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<tr>
<td>ZnO</td>
<td>Nanorods</td>
<td>Wet chemical route</td>
<td>NH3</td>
<td>200</td>
<td>24.1</td>
<td>239/398 s</td>
<td>~50 ppm</td>
<td>181</td>
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<tr>
<td>ZnO</td>
<td>Nanowires</td>
<td>AAO template</td>
<td>NH3</td>
<td>50</td>
<td>68a</td>
<td>28/29 s</td>
<td>~10 ppm</td>
<td>83</td>
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<td>ZnO</td>
<td>Thin film</td>
<td>Spray pyrolysis</td>
<td>NH3</td>
<td>25</td>
<td>233</td>
<td>20/25 s</td>
<td>5 ppm</td>
<td>182</td>
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<td>Thin films</td>
<td>Magnetron sputtering</td>
<td>NH3</td>
<td>100</td>
<td>304</td>
<td>92/113 s</td>
<td>5 ppm</td>
<td>112</td>
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<td>Nanowalls</td>
<td>Solution</td>
<td>NO2</td>
<td>50</td>
<td>~6.2</td>
<td>23/11 s</td>
<td>~5 ppm</td>
<td>91</td>
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<td>Nanowire</td>
<td>Drop-cast</td>
<td>NO2</td>
<td>20</td>
<td>32</td>
<td>72/69 s</td>
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<td>Nanorods</td>
<td>Wet chemical route</td>
<td>NO2</td>
<td>1</td>
<td>100p</td>
<td>~5/~20 min</td>
<td>~1 ppm</td>
<td>110</td>
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<td>ZnO</td>
<td>Nanowires</td>
<td>CVD</td>
<td>NO</td>
<td>10</td>
<td>46a</td>
<td>-</td>
<td>1.5 ppm</td>
<td>184</td>
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<td>Nanocomb</td>
<td>CVD</td>
<td>CO</td>
<td>250</td>
<td>7.22</td>
<td>200/50 s</td>
<td>-</td>
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<td>ZnO</td>
<td>Nanorod array</td>
<td>Microwave hydrolysis</td>
<td>CO</td>
<td>100</td>
<td>81.1a</td>
<td>-2.5 min</td>
<td>10 ppm</td>
<td>72</td>
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<td>Material</td>
<td>Method</td>
<td>Reactant</td>
<td>Temperature</td>
<td>Time</td>
<td>Yield</td>
<td>Purity</td>
<td>Notes</td>
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<td>-------------------</td>
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<tr>
<td>ZnO Nanowires</td>
<td>CVD</td>
<td>H₂</td>
<td>121</td>
<td>8°</td>
<td>29/-s</td>
<td>-</td>
<td>108</td>
<td></td>
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<td>ZnO Nanorods</td>
<td>Chemical deposition</td>
<td>H₂</td>
<td>150</td>
<td>~2°</td>
<td>50-80/-s</td>
<td>-</td>
<td>109</td>
<td></td>
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<tr>
<td>ZnO Nanorods</td>
<td>Hydrothermal</td>
<td>H₂</td>
<td>200</td>
<td>~4°</td>
<td>30s/50-90 s</td>
<td>~1 ppm</td>
<td>110</td>
<td></td>
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<tr>
<td>ZnO Nanotubes</td>
<td>Aqueous chemical</td>
<td>H₂</td>
<td>500</td>
<td>29.6°</td>
<td>-</td>
<td>-</td>
<td>111</td>
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<td>ZnO Thin film</td>
<td>Spray pyrolysis</td>
<td>H₂</td>
<td>150</td>
<td>63</td>
<td>320/200 s</td>
<td>-</td>
<td>112</td>
<td></td>
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<td>ZnO Nanorods</td>
<td>RF magnetron sputtering</td>
<td>H₂</td>
<td>1000</td>
<td>91°</td>
<td>18.8/-130 s</td>
<td>0.2 ppm</td>
<td>113</td>
<td></td>
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<tr>
<td>ZnO Nanorod array</td>
<td>Atomic layer deposition</td>
<td>H₂</td>
<td>500</td>
<td>162</td>
<td>30/-s</td>
<td>5 ppm</td>
<td>114</td>
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<tr>
<td>ZnO Nanorod array</td>
<td>Chemical deposition</td>
<td>H₂</td>
<td>1000</td>
<td>500°</td>
<td>176/116 s</td>
<td>-</td>
<td>115</td>
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<td>MoO₃ Nanoribbons</td>
<td>Hydrothermal</td>
<td>H₂</td>
<td>1000</td>
<td>90°</td>
<td>14.1/- s</td>
<td>0.5 ppm</td>
<td>116</td>
<td></td>
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<tr>
<td>SnO₂ Nano-film</td>
<td>Sol-gel</td>
<td>H₂</td>
<td>1000</td>
<td>2570°</td>
<td>192/95 s</td>
<td>-</td>
<td>117</td>
<td></td>
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<tr>
<td>SnO₂ Nanotubes</td>
<td>Electrospinning</td>
<td>NO₃</td>
<td>9.7</td>
<td>89.2°</td>
<td>6/218 s</td>
<td>9.7 ppb</td>
<td>118</td>
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<tr>
<td>SnO₂ Nanocrystals</td>
<td>Chemical precipitation</td>
<td>NO₂</td>
<td>11</td>
<td>33°</td>
<td>100/250 s</td>
<td>~3 ppm</td>
<td>119</td>
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<td>SnO₂ Thin films</td>
<td>Pulsed laser deposition</td>
<td>NO₂</td>
<td>4</td>
<td>7730</td>
<td>3/176 s</td>
<td>~4 ppm</td>
<td>120</td>
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<td>SnO₂ Thin film</td>
<td>Sol-gel</td>
<td>Ozone</td>
<td>0.5</td>
<td>3.1</td>
<td>15/12 min</td>
<td>-</td>
<td>121</td>
<td></td>
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<td>SnO₂ Nanorods</td>
<td>Microwave</td>
<td>O₂</td>
<td>10</td>
<td>~16.5°</td>
<td>~200/-50 s</td>
<td>~1 ppm</td>
<td>122</td>
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<tr>
<td>SnO₂ Nanoporous</td>
<td>Hydrothermal</td>
<td>Acetone</td>
<td>100</td>
<td>14.64°</td>
<td>30/20 s</td>
<td>~10 ppm</td>
<td>123</td>
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<td>SnO₂ nanocrystals</td>
<td>Sol-gel</td>
<td>NH₃</td>
<td>50</td>
<td>694.4°</td>
<td>175/210 s</td>
<td>-</td>
<td>124</td>
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<td>SnO₂ Nanowires</td>
<td>Precipitation</td>
<td>Ethanol</td>
<td>6000</td>
<td>8000</td>
<td>-</td>
<td>-</td>
<td>125</td>
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<td>In₂O₃ Nanowire</td>
<td>CVD</td>
<td>H₂S</td>
<td>20</td>
<td>2</td>
<td>48/56 s</td>
<td>1 ppm</td>
<td>126</td>
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<td>In₂O₃ Whisker</td>
<td>Carbothermal</td>
<td>H₂S</td>
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<td>30°</td>
<td>4/120 min</td>
<td>200 ppb</td>
<td>127</td>
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<td>In₂O₃ Nanotubes</td>
<td>Electrospinning</td>
<td>H₂S</td>
<td>20</td>
<td>167</td>
<td>287/636 s</td>
<td>~1 ppm</td>
<td>128</td>
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<td>Electrospinning</td>
<td>H₂S</td>
<td>50</td>
<td>320.14</td>
<td>45/127 s</td>
<td>200 ppb</td>
<td>129</td>
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<td>Template</td>
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<td>50</td>
<td>240000</td>
<td>140/- s</td>
<td>1 ppm</td>
<td>130</td>
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<td>NH₃</td>
<td>1000</td>
<td>92°</td>
<td>100/60 s</td>
<td>~250 ppm</td>
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<td>20</td>
<td>2500</td>
<td>&lt;20/20 s</td>
<td>~5 ppm</td>
<td>132</td>
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<td>In₂O₃ Octahedrons</td>
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<td>NO₂</td>
<td>200</td>
<td>~70</td>
<td>~500/-500 s</td>
<td>0.1 ppm</td>
<td>133</td>
<td></td>
</tr>
<tr>
<td>In₂O₃ Mesoporous nanocrystals</td>
<td>Hydrothermal</td>
<td>NO₃</td>
<td>97</td>
<td>158.7°</td>
<td>96/- s</td>
<td>970 ppb</td>
<td>134</td>
<td></td>
</tr>
<tr>
<td>In₂O₃ Cubic crystals</td>
<td>Hydrothermal</td>
<td>Ethanol</td>
<td>100</td>
<td>1.4</td>
<td>5/3 s</td>
<td>~10 ppm</td>
<td>135</td>
<td></td>
</tr>
<tr>
<td>WO₃-x Quantum dots</td>
<td>Solvo thermal</td>
<td>HCHO</td>
<td>100</td>
<td>1.6</td>
<td>2/3 min</td>
<td>1.5 ppm</td>
<td>136</td>
<td></td>
</tr>
<tr>
<td>WO₃ Nanocolumns</td>
<td>Hydrothermal</td>
<td>Isopropanol</td>
<td>200</td>
<td>6.7</td>
<td>53/274 s</td>
<td>1 ppm</td>
<td>137</td>
<td></td>
</tr>
<tr>
<td>Material</td>
<td>Film Type</td>
<td>Deposition Method</td>
<td>Gas Used</td>
<td>Concentration</td>
<td>Response Time</td>
<td>LOD</td>
<td></td>
<td></td>
</tr>
<tr>
<td>-----------</td>
<td>-----------</td>
<td>------------------</td>
<td>----------</td>
<td>---------------</td>
<td>---------------</td>
<td>------</td>
<td></td>
<td></td>
</tr>
<tr>
<td>WO&lt;sub&gt;3&lt;/sub&gt;</td>
<td>Nano-film</td>
<td>Thermal evaporation</td>
<td>Ethanol</td>
<td>30</td>
<td>35&lt;sup&gt;a&lt;/sup&gt;</td>
<td>~300/300 min</td>
<td>~10 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Thin film</td>
<td>Anodic oxidation</td>
<td>NH&lt;sub&gt;3&lt;/sub&gt;</td>
<td>100</td>
<td>0.32&lt;sup&gt;*&lt;/sup&gt;</td>
<td>&lt;2/2 min</td>
<td>~50 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Quantum dot</td>
<td>Hydrolysis method</td>
<td>NH&lt;sub&gt;3&lt;/sub&gt;</td>
<td>0.2</td>
<td>2.13</td>
<td>88/23 s</td>
<td>0.2 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nano-film</td>
<td>Sol-gel</td>
<td>NH&lt;sub&gt;3&lt;/sub&gt;</td>
<td>50</td>
<td>35&lt;sup&gt;a&lt;/sup&gt;</td>
<td>4/6 min</td>
<td>~10 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nano-film</td>
<td>Magnetron sputtering</td>
<td>NH&lt;sub&gt;3&lt;/sub&gt;</td>
<td>100</td>
<td>7857</td>
<td>34/90 s</td>
<td>5 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanoparticles</td>
<td>Sol-gel</td>
<td>NH&lt;sub&gt;3&lt;/sub&gt;</td>
<td>100</td>
<td>10080.8</td>
<td>35.5/59 s</td>
<td>~1 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanodots</td>
<td>Nano-oxidation</td>
<td>NO</td>
<td>10</td>
<td>31&lt;sup&gt;a&lt;/sup&gt;</td>
<td>91/184 s</td>
<td>~5 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>40</td>
<td>1093</td>
<td>48/52 s</td>
<td>0.02 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>CH&lt;sub&gt;4&lt;/sub&gt;</td>
<td>60</td>
<td>6028</td>
<td>-</td>
<td>5 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanorods</td>
<td>Acid vapor oxidation</td>
<td>O&lt;sub&gt;2&lt;/sub&gt;</td>
<td>40000</td>
<td>1.68</td>
<td>40/75 s</td>
<td>1000 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanotubes</td>
<td>Electrochemical anodization</td>
<td>CHCl&lt;sub&gt;3&lt;/sub&gt;</td>
<td>20000</td>
<td>~0.76</td>
<td>~3/- min</td>
<td>1000 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Thin film</td>
<td>Magnetron sputtering</td>
<td>CH&lt;sub&gt;3&lt;/sub&gt;NH&lt;sub&gt;2&lt;/sub&gt;</td>
<td>10</td>
<td>11.3&lt;sup&gt;a&lt;/sup&gt;</td>
<td>200/260 s</td>
<td>~2 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanotube arrays</td>
<td>Electrochemical anodization</td>
<td>HCHO</td>
<td>50</td>
<td>~37&lt;sup&gt;a&lt;/sup&gt;</td>
<td>3/- min</td>
<td>0.04 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanotubes</td>
<td>Electrochemical anodization</td>
<td>Methanol</td>
<td>1000</td>
<td>60&lt;sup&gt;a&lt;/sup&gt;</td>
<td>34/130 s</td>
<td>10 ppm</td>
<td></td>
</tr>
<tr>
<td>TiO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanotubes</td>
<td>Electrochemical anodization</td>
<td>Acetone</td>
<td>100</td>
<td>70.18&lt;sup&gt;a&lt;/sup&gt;</td>
<td>19/14 s</td>
<td>~10 ppm</td>
<td></td>
</tr>
<tr>
<td>Fe&lt;sub&gt;2&lt;/sub&gt;O&lt;sub&gt;3&lt;/sub&gt;</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>H&lt;sub&gt;2&lt;/sub&gt;S</td>
<td>100</td>
<td>38.4</td>
<td>~180/~3700 s</td>
<td>50 ppb</td>
<td></td>
</tr>
<tr>
<td>Fe&lt;sub&gt;2&lt;/sub&gt;O&lt;sub&gt;3&lt;/sub&gt;</td>
<td>Nanonails</td>
<td>Screen printing</td>
<td>LPG</td>
<td>20000</td>
<td>51</td>
<td>120/150 s</td>
<td>5000 ppm</td>
<td></td>
</tr>
<tr>
<td>MoO&lt;sub&gt;3&lt;/sub&gt;</td>
<td>Thin film</td>
<td>Magnetron sputtering</td>
<td>NO</td>
<td>200</td>
<td>92&lt;sup&gt;a&lt;/sup&gt;</td>
<td>30/1500 s</td>
<td>5 ppm</td>
<td></td>
</tr>
<tr>
<td>VO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanorods</td>
<td>CVD</td>
<td>NO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>5</td>
<td>2.42</td>
<td>59/86 s</td>
<td>~1 ppm</td>
<td></td>
</tr>
<tr>
<td>VO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanorods</td>
<td>Thermal evaporation</td>
<td>CH&lt;sub&gt;4&lt;/sub&gt;</td>
<td>500</td>
<td>35&lt;sup&gt;*&lt;/sup&gt;</td>
<td>75/158 s</td>
<td>~100 ppm</td>
<td></td>
</tr>
<tr>
<td>VO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanoneedles</td>
<td>Vapor deposition</td>
<td>Acetone</td>
<td>1.7</td>
<td>1.025</td>
<td>73/- s</td>
<td>941 ppb</td>
<td></td>
</tr>
<tr>
<td>CeO&lt;sub&gt;2&lt;/sub&gt;</td>
<td>Nanowires</td>
<td>Hydrothermal</td>
<td>H&lt;sub&gt;2&lt;/sub&gt;S</td>
<td>0.05</td>
<td>1.11</td>
<td>24/15 s</td>
<td>50 ppb</td>
<td></td>
</tr>
</tbody>
</table>

**Notes:**

- \( C \) = concentration;
- \( t_{\text{res}}/t_{\text{rec}} = \text{response time/recovery time}; \)
- \( \text{LOD} = \text{limit of detection}; \)
- Response is defined as \( R_a/R_g \) (for reducing gases) or \( R_g/R_a \) (for oxidizing gases), \( R_a \): resistance of the sensor exposed to reference, \( R_g \): resistance of the sensor exposed to target:
- \( * \) Here the response is defined as \( \Delta R/R_g \) (for reducing gases) or \( \Delta R/R_a \) (for oxidizing gases), \( \Delta R \): the change in resistance.
# Here the response is defined as \((\Delta R/R_g) \times 100\%\) (for reducing gases) or \((\Delta R/R_a) \times 100\%\) (for oxidizing gases).

## 2.1.1 Gas sensing mechanisms

Gas sensing mechanism of semiconductor oxides based resistive sensor is mostly based on the changes of resistance after they are exposed to the target gases due to the chemical interactions between target gas molecules and the adsorbed oxygen ions on the surface of SMONs\(^{153,154}\). Conductance of n-type SMONs relies on electron carriers. When the n-type SMONs are surrounded by air, the oxygen molecules are absorbed on their surfaces. The absorbed oxygen molecules extract electrons from the conduction band of surface layer, which results in the formation of negatively charged chemisorbed oxygen ions including \(\text{O}_2^-, \text{O}^-\) and \(\text{O}^{2-}\) at different operating temperatures. Due to the decrease in the electron density, an electron depletion layer is formed on the surface of SMONs and a potential barrier is generated\(^{42,43}\). Therefore, the conductivity of the SMONs decreases, thus resulting in an increased resistance.

The operation temperature of gas sensors determines the types of chemisorbed oxygen ions. For example, they are mainly \(\text{O}_2^-\) when the temperature is below 100 °C. When the working temperature is increased between 100 °C and 300 °C, the \(\text{O}_2^-\) ions will capture electrons and then transfer into \(\text{O}^-\) ions. The \(\text{O}^-\) can be converted into \(\text{O}^{2-}\) ions at a higher working temperature above 300 °C. The formation process of oxygen ions can be summarized using the following equations\(^{42,43}\):  

\[
\text{O}_2 \text{(gas)} \leftrightarrow \text{O}_2 \text{(ads)} \tag{1}
\]
\[
\text{O}_2 \text{(ads)} + e^- \leftrightarrow \text{O}_2^- \text{(ads)} \quad (<100 \ \text{oC}) \tag{2}
\]
\[
\text{O}_2^- \text{(ads)} + e^- \leftrightarrow 2\text{O}^- \text{(ads)} \quad (100 \ \text{oC}-300 \ \text{oC}) \tag{3}
\]
\[
\text{O}^- \text{(ads)} + e^- \leftrightarrow \text{O}^{2-} \text{(ads)} \quad (>300 \ \text{oC}) \tag{4}
\]

Therefore, at RT, the oxygen ions on the surface of n-type SMONs is mainly \(\text{O}_2^-\) ions. When the sensor is exposed to the target gases, the gas molecules are absorbed on the surface of SMONs, and then react with these chemisorbed oxygen ions.
If the target gases are reducing gases, such as H$_2$S, H$_2$, NH$_3$, HCHO, or C$_2$H$_5$OH, the chemical reaction releases electrons, which are reinjected back to the electron depletion layer (see Fig. 3, the schematic diagram for H$_2$S gas sensing mechanism). This results in the reduction of the electron depletion layer and reduces the potential barrier energy ($\Delta\phi$). As a result, the surface resistance of SMONs is decreased. On the contrary, if the target gases are oxidizing gases, such as NO, NO$_2$, Cl$_2$ and O$_3$, the reaction with the chemisorbed oxygen ions will capture the electrons, which will widen the electron depletion layer, resulting in an increase of the potential barrier energy ($\Delta\phi$). Accordingly, the surface resistance of the SMONs is increased.

There are generally three definitions for the response values of n-type SMON based gas sensor, which are $Ra/R_g$, $(Ra-R_g)/R_g$ and $(Ra-R_g)/R_g \times 100\%$ for the target reducing gases, respectively (where R$_g$ and R$_a$ are the resistance of sensors in the target gas and air, respectively). Whereas for the oxidizing gases, Ra and R$_g$ need to be interchanged in the above three definitions. The time from the injection of the targeting gas to the time of reaching the 90% of the final response is defined as the response time, and the time from the extraction of the gas to the time of reaching 10% of the final response is defined as the recovery time.

Generally, formation of chemisorbed oxygen ions determines the sensing performance. However, the gas sensing mechanism is sometimes attributed to the formation of new compounds as a result of reactions between the target gas and the
surface of the SMONs. For example, H₂S gas molecules can react with ZnO to form ZnS at RT \(^{71, 109}\). Formation of such type of conductive metal sulfide significantly decreases the resistance of the SMON-based sensors, which accounts for high sensitivities of n-type SMONs-based sensors for H₂S.

Chemical and electronic sensitization of the SMONs can be realized by adding noble metals on their surface and thus can remarkably enhance their sensing properties. Surface modifications and introduction of defects on the surfaces and interfaces such as introduction of heterojunctions \(^{134}\) and vacancies \(^{117}\) influence the sensing performance of SMONs sensing materials. Addition of carbon nanomaterials on the surface of SMONs can also significantly improve their conductivity and enhance their RT sensitivities at RT \(^{135}\). In addition, the alkaline center \(^{129}\) and hydroxide radicals \(^{198}\) on the surfaces of SMONs have also been reported to affect the sensing properties, which will be discussed further.

### 2.1.2 Room temperature hydrogen sulfide sensors

N-type SMONs based on ZnO \(^{152}\), In\(_2\)O\(_3\) \(^{199}\), CeO\(_2\) \(^{86}\) and Fe\(_2\)O\(_3\) \(^{80}\) have frequently been reported for H₂S gas sensing at RT. Among these, ZnO and In\(_2\)O\(_3\) are wide band-gap semiconductors, with their band gaps of 3.3 eV and 3.6 eV, respectively. They are very effective for H₂S sensing because H₂S molecules can be easily decomposed and react with the chemisorbed oxygen species on the surface of these sensing material due to the small bond energy of H-S-H. On the surface of ZnO or In\(_2\)O\(_3\), the H₂S molecules not only react with the oxide ions of O\(^2^-\) to form SO\(_2\) and H\(_2\)O, but also react with ZnO or In\(_2\)O\(_3\) to form ZnS or In\(_2\)S\(_3\), based on the following reactions \(^{71, 101, 109}\):

\[
2\text{H}_2\text{S} (g) + \text{O}_2^- (\text{ads}) \leftrightarrow 2\text{H}_2\text{O} (g) + 2\text{SO}_2 (g) + 3e^- \]  \(\text{(5)}\)

\[
\text{ZnO} + \text{H}_2\text{S} (\text{ads}) \rightarrow \text{ZnS} + \text{H}_2\text{O} \]  \(\text{(6)}\)

\[
\text{In}_2\text{O}_3 + 3\text{H}_2\text{S} (\text{ads}) \rightarrow \text{In}_2\text{S}_3 + 3\text{H}_2\text{O} \]  \(\text{(7)}\)

The reactions with the oxide ions increase electron concentrations on the surface of ZnO or In\(_2\)O\(_3\), which lead to a significant decrease in resistance. Because the ZnS and In\(_2\)S\(_3\) are metallic conductors, the formation of ZnS or In\(_2\)S\(_3\) also decreases the resistance of sensors, thus the responses to the gases are enhanced significantly at RT.
Formation of ZnS or In$_2$S$_3$ is an exothermic process and spontaneously occurs at RT, so the sensors based on ZnO or In$_2$O$_3$ nanostructures are very suitable to detect H$_2$S at RT. Due to the formation of these metal sulfides, which are not reactive to most of other gases, such as NH$_3$, H$_2$, NO$_2$, CO, CH$_4$, C$_2$H$_5$OH, HCHO, the selectivity of RT sensors made of the nanostructured ZnO or In$_2$O$_3$ to H$_2$S is excellent. Therefore, the ZnO and In$_2$O$_3$ nanostructured gas sensors generally have high response and excellent selectivity for the H$_2$S gas sensing.

Reaction of metal sulfides in sensing process and the transformation of metal sulfides back to metal oxides in the recovery process are sometimes very slow at RT. Therefore, for the RT H$_2$S gas sensors, the response time and especially the recovery time are often relatively long, sometimes as long as several hours\textsuperscript{71,109}. Furthermore, the sensors may not fully recover at RT\textsuperscript{101}. The sensor is often needed to heat to a relatively higher temperature (e.g. 200  difíc{oc} to 300  difíc{oc}) in the recovery process for a complete recovery or shortening of the recovery time down to minute-scales\textsuperscript{109}.

Fig. 4. (a) Cross-section SEM image of vertically aligned ZnO rods; (b) selectivity of the sensor at 25°C and 250 °C; (c) response/recovery curves to 1 and 5 ppm H$_2$S at room temperature.\textsuperscript{71, © 2015 Elsevier.} (d) The response/recovery curve at 50 ppm H$_2$S gas at room temperature.\textsuperscript{101, © 2017 Elsevier.}
Hosseinia *et al.* \(^7\) prepared vertically aligned ZnO rods with a diameter of 300-500 nm and a length of 1-9.5 µm using a vapor phase transport method. The nanorods are grown along the c-axis or (002) planes perpendicularly to the substrate surface as shown in Fig. 4a. The porous network of vertically aligned ZnO rods forms directional channels, which facilitates the mobility of gas molecules. As shown in Fig. 4b, the sensor based on the vertically aligned ZnO rods shows much higher response to H\(_2\)S at 26 °C than that at 250 °C, and its response value for H\(_2\)S at RT is almost 600 times larger than those for other gases, such as CH\(_4\), CO, H\(_2\)S, methanol, ethanol, acetone, H\(_2\) and He. Whereas at 250 °C, it is less than twice of the original value. The response and recovery times of this sensor are very long, which are 320 s and 3592 s for 1 ppm H\(_2\)S as shown in Fig. 4c. ZnO nanorods were also grown using a hydrothermal method with the diameters of 70-110 nm and length of 0.2-1.3 µm and then used for H\(_2\)S sensing \(^10\). These sensors exhibit a high response (about 35 to 1 ppm H\(_2\)S) and a very low LOD (50 ppb). However, its response time is longer than 20 min, and the sensor is difficult to be recovered at RT. Response and recovery rates of RT H\(_2\)S gas sensors can be improved using dendritic ZnO nanostructures prepared using a vapor-phase transport method with Cu as catalyst at 930 °C \(^15\). The multilevel branches of ZnO have well-oriented nanorods with diameters of 60 to 800 nm. The response/recovery times are 20/50 s, which make this sensor the fastest SMON-based H\(_2\)S sensor at RT reported so far. The sensor exhibits a high response of 26.4 to 500 ppm H\(_2\)S and a good selectivity against various gases including H\(_2\)S, NH\(_3\), H\(_2\) and NO\(_2\) in dry air at RT. The large degree modulation of the contact energy barriers due to the H\(_2\)S gas in ZnO dendrites is the key reason for their excellent sensing performance at RT.

Nanostructured In\(_2\)O\(_3\) is another widely studied material for H\(_2\)S sensing. Apart from reactions of H\(_2\)S gas with oxygen ions on the surface of In\(_2\)O\(_3\), the formation of In\(_2\)S\(_3\) is another key factor for the sensor’s high response at RT. Remarkably, the response value of the In\(_2\)O\(_3\) nanostructure can reach to 240000 for 50 ppm of H\(_2\)S at RT \(^10\) as shown in Fig. 4d. The micro/nanostructured porous In\(_2\)O\(_3\) film was synthesized onto an Al\(_2\)O\(_3\) ceramic tube using a self-assembly method \(^10\), which has an ordered porous structure with a thickness of 200 nm. Although the sensor does not fully recover to its baseline...
at RT, it can be rapidly and completely recovered at 300 °C. Using a conventional electrospinning process, Duan et al.\textsuperscript{100} prepared In$_2$O$_3$ thick walled toruloid nanotubes. Owing to their larger surface areas, the nanotubes have more active sites among them, which results in enhanced responses to H$_2$S gas. The sensors based on the In$_2$O$_3$ nanotubes exhibit high response values of 320.14 to 50 ppm H$_2$S and fast response/recovery times of 45/127 s at the RT. In addition, a good selectivity and a very low LOD with a value of 100 ppb have been demonstrated\textsuperscript{100}. Porous In$_2$O$_3$ nanotubes with a cubic phase have been prepared using the electrospinning method\textsuperscript{161}, and a high response value of 166.6 to 20 ppm H$_2$S has been demonstrated. However, the response/recovery times are quite long (287/636 s).

Other n-type SMONs such as α-Fe$_2$O$_3$\textsuperscript{80} and CeO$_2$\textsuperscript{86} have also been reported as good sensing materials for H$_2$S sensing at RT. For example, porous α-Fe$_2$O$_3$ nanoparticles with a diameter of 34 nm and pore sizes from 2 nm to 10 nm were obtained after annealing a FeOOH nanoparticles precursor\textsuperscript{80}. The sensor based on these porous α-Fe$_2$O$_3$ nanoparticles exhibits a high sensitivity (38.4 for 100 ppm H$_2$S) with a low LOD (50 ppb). In addition, it has a good selectivity to H$_2$S against the other gases (e.g., C$_2$H$_5$OH, CO, H$_2$ and NH$_3$) and shows a good reproducibility. The response time is fast with a value of 180 s. However, the recovery time is very long with a value of 3750 s for 100 ppm H$_2$S. CeO$_2$ nanowires\textsuperscript{86} were also synthesized using a facile hydrothermal process and they show fast response/recovery times with values of 24/15 s for 50 ppb H$_2$S.

For the α-Fe$_2$O$_3$ and CeO$_2$ nanostructure-based H$_2$S gas sensors, the main sensing mechanism is the interactions of the H$_2$S molecules with the oxygen ions on its surface. Accordingly, the sensing is much faster than those sensors based on ZnO and In$_2$O$_3$, although their response to H$_2$S is much lower\textsuperscript{80,86}.

2.1.3 Room temperature nitrogen dioxide sensors

Various SMONs based gas sensors have demonstrated excellent sensing performance at RT for NO$_2$ gas sensing, using different materials such as ZnO\textsuperscript{110,200,201}, SnO$_2$\textsuperscript{76}, In$_2$O$_3$\textsuperscript{196} and WO$_3$\textsuperscript{202-206}, Sb$_2$O$_5$\textsuperscript{207}, Bi$_2$O$_3$\textsuperscript{208} etc. The sensing mechanism
of SMONs to the NO₂ is based on the formation of NO₂⁻ by capturing electrons and the reaction between NO₂ gas molecules and O₂⁻ ions on the surface of the SMONs. All these reactions extract electrons from the surface of the SMONs, thus resulting an increase in the resistance of these sensors, based on the following reactions:

\[ \text{NO}_2\text{(gas)} + e^- \leftrightarrow \text{NO}_2^-\text{(ads)} \]  
\[ \text{NO}_2^-\text{(ads)} + \text{O}_2^-\text{(ads)} + 2e^- \leftrightarrow \text{NO}\text{(gas)} + 2\text{O}_2^-\text{(ads)} \]

One of the outstanding features of SMON-based RT NO₂ gas sensors is their fast response speeds due to the strong oxidation of NO₂ molecules. Kodu et al. 157 reported NO₂ sensors based on granular SnO₂ thin film with a thickness of ~90 nm deposited using a pulsed laser deposition method. The sensor exhibits not only a remarkably high response value of 7730 to 4 ppm NO₂, but also a very fast response time of 3 s at RT. Wei et al. 76 prepared SnO₂ nanocrystals by annealing the Sn(OH)₄ precursor powders at 550 °C in both vacuum and ambient air environments, respectively. The vacuum-annealed SnO₂ and air-annealed SnO₂ nanocrystals have different particle diameters of 7.2 nm and 10.3 nm as shown in Fig. 5a. The response value of the vacuum-annealed SnO₂ sensor at RT is ~2.4 to 5 ppm of NO₂, which is higher than that of air-annealed SnO₂ (~0.35). This is mainly because the increased oxygen vacancies on the surface of

Fig. 5. (a) Response of vacuum-annealed SnO₂ compared to air-annealed SnO₂ nanocrystals to different concentrations of NO₂ at room temperature, the inset shows the TEM images of two types of nanocrystals; (b) and (c) deconvolution of the O 1s peaks of X-ray photoelectron spectroscopy (XPS) for vacuum-SnO₂ and air-SnO₂ (the peaks with red color belong to adsorbed O ions). 76, 2016 Elsevier.
the vacuum-annealed SnO$_2$ are much more than those on the air-annealed SnO$_2$ nanocrystals, which can be identified by X-ray photoelectron spectroscopy (XPS) analysis as shown in Figs. 5b and 5c.

Yu et al. $^{91}$ prepared ZnO nanowalls with uniformly distributed and cross-linked nanowalls of $\sim$20 nm using a solution method. The cross-linked nanowalls have a porous structure with pore sizes from 200 nm to 500 nm. The sensor exhibits a high response value (6.4) and fast response/recovery times (23/11 s) towards 50 ppm NO$_2$ at RT with a good repeatability. Based on the analysis from fluorescence emission spectrum, it was identified $^{82}$ that the key factors for effective NO$_2$ sensing are: (1) the presence of oxygen vacancies in the ZnO nanowall nanostructures, and (2) a delicate balance between oxygen vacancies defects and porosity.

TiO$_2$ and In$_2$O$_3$ are two other frequently reported nanomaterials for NO$_2$ sensing. Tshabalala et al. $^{79}$ prepared TiO$_2$ nanoparticles with an average particle size of 6.5 nm using a hydrothermal method. The fluffy and porous TiO$_2$ layer has a pore volume of 0.4170 cm$^3$/g and a large surface areas of 80.3 m$^2$/g $^{79}$. The porous nanostructures, high concentration of oxygen vacancies and the interstitial defect states on the surface are crucial for the efficient adsorption and desorption of NO$_2$ gas molecules. Therefore, the sensor made of these nanostructures exhibits a high response (1093 to 40 ppm NO$_2$), fast response/recovery times of 48/52 s and a low LOD of 0.02 ppm at RT. However, the selectivity of this sensor is poor with its relatively high responses to many other gases such as H$_2$, NH$_3$ and CH$_4$. In$_2$O$_3$ octahedrons have also been prepared using the sol-gel technique for NO$_2$ sensing $^{102}$, and the sensor using these In$_2$O$_3$ octahedrons has a response value of 63 to 200 ppm NO$_2$ at RT, with a good selectivity to NO$_2$ against CO, H$_2$ and NH$_3$.

### 2.1.4 Room temperature ammonia sensors

The sensing mechanism of SMON-based ammonia gas sensors operated at RT is also based on the reactions between NH$_3$ gas molecules and adsorbed O$_2^-$ ions on the surfaces of the SMONs as shown in the following reactions $^{92,183}$:

$$\text{NH}_3\text{(gas)} \rightarrow \text{NH}_3\text{(ads)}$$  \hspace{1cm} (10)
Majority of the single phase n-type SMONs without modifications by other elements can be used for NH$_3$ gas sensors, including ZnO$^{210-212}$, In$_2$O$_3^{111}$, SnO$_2^{213}$, SnS$_2^{214}$, MoO$_3^{215}$, WO$_3^{216}$ and TiO$_2^{217}$. They have good RT performance for NH$_3$ sensing with high response and fast response/recovery. Among these, the sensors based on In$_2$O$_3$ and TiO$_2$ exhibit ultra-high responses and response/recovery times. For example, a RT sensor based on TiO$_2$ nanoparticles has an ultra-high response of 10080.8 to 100 ppm of NH$_3$ and fast response/recovery times of 35.5/59 s$^{78}$.

Du et al.$^{111}$ reported a RT NH$_3$ gas sensor using porous In$_2$O$_3$ nanotubes. This gas sensor exhibits an ultra-high response value of 2500 and a good reproducibility with response and recovery times less than 20 s, both of which are better than those of the sensors made of In$_2$O$_3$ nanowires or nanoparticles. The performance enhancement is attributed to the porous structure and ultra-high surface-to-volume ratio of the porous In$_2$O$_3$ nanotubes, which can adsorb more oxygen molecules. Another gas sensor made
of TiO$_2$ films prepared using a reactive magnetron sputter method also exhibits an excellent response with a value of 7857 to 100 ppm of NH$_3$, fast response/recovery times of 34/90 s and a low LOD of ~5 ppm$^{174}$. Kumar et al.$^{83}$ used an anodic aluminum oxide template route to prepare highly ordered ZnO nanowire arrays as the sensing layer for detection of NH$_3$. The diameters of these nanowires are in the range of 60 to 70 nm and their length is about 11 μm as shown in Fig. 6a. At the RT, the sensor exhibits 68% of response value (defined as (ΔR/Rg)×100%) to 50 ppm NH$_3$ and fast response/recovery times (28/29 s) (see Fig. 6b) $^{83}$. Another NH$_3$ sensor made of nanostructured ZnO thin films $^{112}$ synthesized using a magnetron sputtering technique shows a high response with a value of 304 to 100 ppm NH$_3$ with response/recovery times of 92/113 s.

Mani et al.$^{182}$ reported a sensor made of a nanostructured ZnO thin film (shown in Fig. 6c) using a spray pyrolysis technique. As shown in Fig. 6d, the sensor using this thin film exhibits a high response with a value of 233 to 25 ppm of NH$_3$ at RT, and fast response and recovery times of 20/25 s. It has a good selectivity to ammonia gas against other VOC gases (i.e. ethanol, methanol, benzyl alcohol, 2-propanol and acetone). Moreover, the sensor is insensitive to relative humidity. However, the sensor becomes saturated when the concentration of NH$_3$ is above 20 ppm, indicating that the LOD is about from 5 ppm to 25 ppm. In brief, high response, fast response/recovery, and superior LOD have been achieved for the n-type SMON-based RT NH$_3$ gas sensors.

### 2.1.5 Room temperature ethanol sensors

Most n-type SMONs made of ZnO$^{218-220}$, Fe$_2$O$_3$$^{221}$, SnO$_2$$^{222}$, In$_2$O$_3$$^{105}$, TeO$_2$$^{85}$ and WO$_3$$^{106}$ can be used for ethanol sensing. The sensing mechanism of n-type SMON-based ethanol gas sensors is based on the interaction of ethanol gas molecules with chemisorbed O$_2^-$ ions on the surfaces of the SMONs. The ethanol molecules react with the adsorbed oxygen ions to form CO$_2$ and H$_2$O. Subsequently, electrons are released thus resulting in an increase in electron density and a decrease in potential barrier energy. These can be expressed using the following reactions$^{180}$.

\[
\text{CH}_3\text{CH}_2\text{OH}_{(\text{gas})} \rightarrow \text{CH}_3\text{CH}_2\text{OH}_{(\text{ads})}
\]  

(12)
\[ \text{C}_2\text{H}_5\text{OH} + 3\text{O}_2^{-} \text{(ads)} \rightarrow 2\text{CO}_2 + 3\text{H}_2\text{O} + 3e^- \]  

(13)

Fig. 7. (a) Responses of the ZnO nanowire sensor to different concentrations of ethanol at room temperature, the inset shows the SEM image of ZnO nanowire; (b) the schematic diagram of ethanol sensing mechanism. \(^{82}\), © 2017 American Chemical Society.

The RT ethanol gas sensors based on the n-type SMONs usually exhibit rapid response and recovery. For example, a sensor based on \(\text{In}_2\text{O}_3\) cubic crystals \(^{105}\) prepared using a hydrothermal method exhibits very fast response/recovery (3/5 s). However, the response is poor with a value of only 1.4 to 100 ppm ethanol vapors. The fast response/recovery times together with high responses have been reported for the sensor made of ZnO nanowires \(^{82,180}\). Shankar \textit{et al.} \(^{82}\) reported an ethanol sensor made of ZnO nanowires (see Fig. 7a) prepared using the electrospinning. The self-assembled ZnO nanowires with two different molecular weights of poly(vinyl alcohol) (PVA), e.g., 14000 and 140000 g/mol, were prepared using an electrospinning technique, and then heat-treated to transform them into ZnO nanospheres and nanowires at a temperature of 600 °C. These nanostructures have a good selectivity to ethanol compared to other VOCs including ethanol, methanol, acetaldehyde, and acetone when operated at RT. The nanowires based sensors have a higher ethanol response (78 to 100 ppm) than those based on the nanoparticles (about 48 to 100 ppm) \(^{76}\). The nanowire-based ones also show fast response/recovery times of 9/12 s. Furthermore, the nanowire-based sensor has an excellent repeatability.

Fig. 7b shows a schematic diagram of ethanol sensing mechanism for the ZnO-based sensor \(^{82}\). The chemisorption of oxygen molecules on the sensor surface results in the
formation of a space charge region on the surface of ZnO, which can act as a barrier for electron transports in the ZnO sensing layer\textsuperscript{82}. Due to the formation of double-spaced charge layers from the intergranular contacts of nanoparticles, the potential barrier energy is increased, which results in the broadening of the percolation path and hinders the electron transport. This further influences the adsorption–desorption rate and the sensing properties to ethanol. However, the intergranular contact resistance will be reduced in the ZnO nanowires, which decreases the potential barrier energy, thus enhancing the sensing performance.

Similarly, TiO\textsubscript{2} nanotubes\textsuperscript{96} prepared using an electrochemical anodization method and TeO\textsubscript{2} nanowires\textsuperscript{85} prepared using thermal evaporation also show good responses to ethanol\textsuperscript{85,96}. However, the selectivity is poor as they are also sensitive to methanol and propanol.

### 2.1.6 Room temperature hydrogen sensors

![Fig. 8](image)

Fig. 8. (a) AFM image of the ZnO films and (b) response/recovery curves of ZnO film-based gas sensor to different concentrations of H\textsubscript{2}.\textsuperscript{189}, © 2014 Springer Nature. (c) Cross section SEM image of the ZnO nanorods and (d) response/recovery curves of ZnO nanorod-based gas sensor to different concentrations of H\textsubscript{2}.\textsuperscript{191}, © 2013 Elsevier.

Hydrogen gas is one of the extremely flammable and explosive gases. Therefore,
detection of traces of hydrogen gas using the RT gas sensors is critical to avoid the dangers of explosion. For this application, the sensors must be fast, highly sensitive and selective. In particular, the fast response is paramount for a timely detection of a possible hydrogen leakage. As summarized in Table 1, the SMONs made of ZnO, MoO₃, and SnO₂ have been demonstrated for hydrogen sensing at RT using various nanostructures including nanofilm, nanowires, nanotubes and nanorods. The sensing mechanism is based on the reaction of H₂ molecules with chemisorbed O²⁻ ions on the surface of the SMONs, as shown in the following chemical equation:

\[ 2\text{H}_2 + O_2^{\text{(ads)}} \rightarrow 2\text{H}_2\text{O} + e^- \]  

(14)

From the literature, sensors made from ZnO films and ZnO nanorods show high responses to H₂, but long response/recovery times (see Fig. 8).

Fig. 9. (a) TEM image of vertical ZnO nanorods; (b) Response/recovery curves of vertical ZnO nanorods-based gas sensor versus different concentrations of H₂. © 2012 Elsevier. (c) SEM images of α-MoO₃ nanoribbons; (d) response values and times of α-MoO₃ nanoribbons-based gas sensor versus different concentrations of H₂. © 2015 American Chemical Society.

Using anodized aluminum oxides as nano-templates, Lim et al. synthesized vertical ZnO nanorods (see Fig. 9a) using atomic layer deposition, and a highly
sensitive and fast response/recovery H$_2$ gas sensor was fabricated using these vertical ZnO nanorods. A response value of 162 for 500 ppm H$_2$ and a response time of 30 s were demonstrated (see Fig. 9b) [193]. A faster response H$_2$ gas sensor was also reported using [001]-oriented α-MoO$_3$ nanoribbons (see Fig. 9c) [192] with a response time of 14.1 s for 1000 ppm of H$_2$ and a low LOD of 500 ppb (see Fig. 9d) [192]. It has a good reproducibility and a high selectivity against ethanol, CO and acetone.

In brief, the RT gas sensor based the n-type SMONs can detect most type of hazardous gases, with advantages such as easy preparation, low cost, simple post-treatment and good stability of structure. Various morphologies of nanostructures for the n-type SMONs have been synthesized and used into the gas sensors operated at the RT. These sensors have been widely used to detect various gases and some good sensing properties have been achieved. However, it should be addressed that for most of these n-type SMON-based RT gas sensors, their sensitivity at RT is much lower than that at a higher working temperatures. Their responses and recovery times are quite long, and sometimes these sensors cannot be fully recovered at RT. In addition, at RT, the sensing performance is seriously affected by various environmental factors, such as humidity and external light source. To enhance their sensing properties at RT, modification of these n-type SMONs should be adopted, which will be discussed in Section 3.

### 2.2 P-type semiconducting metal oxide nanostructures and gas sensors

Up to now, the major p-type SMONs used in RT gas sensing are CuO $^{223-225}$, Co$_3$O$_4$ $^{92, 103}$ and NiO $^{94, 226}$, and the main target gases include NH$_3$ $^{98, 103}$, H$_2$S $^{224, 225}$ and NO$_2$ $^{226}$, as listed in Table 2. Apart from the sensing mechanism which is based on the reaction of target gases with the oxygen ions on the surface of SMONs, the formation of metal sulfides is another key reason for H$_2$S sensing, especially for CuO nanostructures $^{93, 225}$.

Table 2 Summary of room temperature sensing properties of p-type semiconducting metal oxide nanostructures
<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>$t_{\text{res}}/t_{\text{rec}}$</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>CuO</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>H$_2$S</td>
<td>0.01</td>
<td>1.25</td>
<td>234/76 s</td>
<td>10 ppb</td>
<td>93</td>
</tr>
<tr>
<td>CuO</td>
<td>Thin films</td>
<td>Thermal evaporation</td>
<td>H$_2$S</td>
<td>5</td>
<td>$\sim$250$^a$</td>
<td>60/90 s</td>
<td>100 ppb</td>
<td>224</td>
</tr>
<tr>
<td>CuO</td>
<td>Flower</td>
<td>Hydrothermal</td>
<td>H$_2$S</td>
<td>1</td>
<td>2.1</td>
<td>240/1341 s</td>
<td>0.1 ppm</td>
<td>225</td>
</tr>
<tr>
<td>CuO</td>
<td>Tube</td>
<td>Biotemplate</td>
<td>H$_2$S</td>
<td>5</td>
<td>$\sim$41</td>
<td>29/41 s</td>
<td>2 ppb</td>
<td>98</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanofibers</td>
<td>Electrospinning</td>
<td>H$_2$S</td>
<td>100</td>
<td>2.23</td>
<td>4.3/- s</td>
<td>1 ppm</td>
<td>227</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanoparticles</td>
<td>Sol-gel-combustion</td>
<td>NH$_3$</td>
<td>100</td>
<td>9.83$^*$</td>
<td>$\sim$150/$\sim$500 s</td>
<td>-</td>
<td>81</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanoparticles</td>
<td>Sol-gel-combustion</td>
<td>NH$_3$</td>
<td>100</td>
<td>0.99$^*$</td>
<td>30/- s</td>
<td>-</td>
<td>228</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanorectangles</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>5</td>
<td>$\sim$0.25$^*$</td>
<td>90/120 s</td>
<td>5 ppm</td>
<td>223</td>
</tr>
<tr>
<td>CuO</td>
<td>Microspheres</td>
<td>Reflux method</td>
<td>NO$_2$</td>
<td>97</td>
<td>64.93$^a$</td>
<td>5.33/- s</td>
<td>0.97 ppm</td>
<td>90</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanostructural</td>
<td>Sonochemical method</td>
<td>NO$_2$</td>
<td>40</td>
<td>53737</td>
<td>-</td>
<td>-</td>
<td>229</td>
</tr>
<tr>
<td>Cu$_2$O</td>
<td>Virus-like</td>
<td>Chemical solution</td>
<td>NO$_2$</td>
<td>4</td>
<td>28.1</td>
<td>22/42 s</td>
<td>1 ppm</td>
<td>230</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanowires</td>
<td>Thermal oxidation</td>
<td>Ethanol</td>
<td>100</td>
<td>202</td>
<td>0.19/0.19 s</td>
<td>$\sim$10 ppm</td>
<td>36</td>
</tr>
<tr>
<td>CuO</td>
<td>Nanoribbons</td>
<td>Wet chemical</td>
<td>Ethanol</td>
<td>100</td>
<td>210$^a$</td>
<td>8/25 s</td>
<td>20 ppm</td>
<td>231</td>
</tr>
<tr>
<td>NiO</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>60</td>
<td>3.05$^a$</td>
<td>$\sim$200/$\sim$300 s</td>
<td>$\sim$5 ppm</td>
<td>94</td>
</tr>
<tr>
<td>NiO</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>60</td>
<td>1.8$^*$</td>
<td>$\sim$250/$\sim$250 s</td>
<td>$\sim$7 ppm</td>
<td>226</td>
</tr>
<tr>
<td>NiO</td>
<td>Nanosheets</td>
<td>Microwave synthesis</td>
<td>NO$_2$</td>
<td>10</td>
<td>0.56</td>
<td>-</td>
<td>-</td>
<td>232</td>
</tr>
<tr>
<td>NiO</td>
<td>Dendritic-like</td>
<td>Electrolytic</td>
<td>NH$_3$</td>
<td>30</td>
<td>19$^a$</td>
<td>40/1500 s</td>
<td>-</td>
<td>233</td>
</tr>
<tr>
<td>Co$_3$O$_4$</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>100</td>
<td>9.5</td>
<td>9/134 s</td>
<td>0.2 ppm</td>
<td>92</td>
</tr>
<tr>
<td>Co$_3$O$_4$</td>
<td>Porous structure</td>
<td>Template</td>
<td>NH$_3$</td>
<td>100</td>
<td>146$^a$</td>
<td>2/- s</td>
<td>0.5 ppm</td>
<td>103</td>
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<td>Co$_3$O$_4$</td>
<td>Nanoparticles</td>
<td>Thermal treatment</td>
<td>NO$_2$</td>
<td>100</td>
<td>52.1$^a$</td>
<td>-</td>
<td>100 ppb</td>
<td>234</td>
</tr>
<tr>
<td>Co$_3$O$_4$</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>CO</td>
<td>50</td>
<td>-</td>
<td>15/ 20s</td>
<td>-</td>
<td>235</td>
</tr>
<tr>
<td>Cr$_2$O$_3$</td>
<td>Nanospheres</td>
<td>Hydrothermal</td>
<td>Ethanol</td>
<td>40</td>
<td>9$^a$</td>
<td>-</td>
<td>5 ppm</td>
<td>236</td>
</tr>
<tr>
<td>Cr$_2$O$_3$</td>
<td>Mesoporous</td>
<td>Impregnation</td>
<td>Ethanol</td>
<td>1000</td>
<td>13.0</td>
<td>-</td>
<td>10 ppm</td>
<td>237</td>
</tr>
<tr>
<td>$\beta$-MnO$_2$</td>
<td>Thin films</td>
<td>Spray pyrolysis</td>
<td>CH$_3$COH</td>
<td>10</td>
<td>89$^a$</td>
<td>60/11 s</td>
<td>10 ppm</td>
<td>238</td>
</tr>
<tr>
<td>MnO$_2$</td>
<td>Nanofibers</td>
<td>Chemical solution</td>
<td>NH$_3$</td>
<td>100</td>
<td>20$^a$</td>
<td>-</td>
<td>1 ppm</td>
<td>239</td>
</tr>
<tr>
<td>$\alpha$-MnO$_2$</td>
<td>Nanospheres</td>
<td>Self-assembly</td>
<td>NH$_3$</td>
<td>20 000</td>
<td>0.2</td>
<td>-</td>
<td>-</td>
<td>240</td>
</tr>
</tbody>
</table>

**Notes:**

$C =$ concentration;  
$t_{\text{res}}/t_{\text{rec}} =$ response time/recovery time;  
LOD = limit of detection;  
Response is defined as $R_a/R_g$ (for reducing gases) or $R_g/R_a$ (for oxidizing gases), $R_a$: resistance of the sensor exposed to reference, $R_g$: resistance of the sensor exposed to
target:
* Here the response is defined as $\Delta R/R_g$ (for reducing gases) or $\Delta R/R_a$ (for oxidizing gases). $\Delta R$: the change in resistance.
# Here the response is defined as $(\Delta R/R_g) \times 100\%$ (for reducing gases) or $(\Delta R/R_a) \times 100\%$ (for oxidizing gases).

2.2.1 Gas sensing mechanisms

Fig. 10. Schematic diagram of sensing mechanism for p-type semiconducting metal oxide nanostructures to reducing gas of NH$_3$.

Generally, the sensing mechanism of p-type SMONs is based on the changes of surface resistance as a result of the changes in the concentrations of hole carriers due to their redox reaction with the target gases. When exposed to air at RT, the oxygen ions of O$_2^-$ are formed from the adsorbed oxygen molecules on the surface of p-type semiconductor and they capture electrons from the conduction band of the SMONs. The density of hole carriers is increased, thus resulting in the decrease in the surface layer’s Fermi level. Due to an accumulated hole layer formed on the surface of p-type SMONs, the conductivity will be increased and the resistance of the sensors is decreased. This is opposite to the sensing mechanism for the n-type SMONs sensors discussed in the last section.

The sensing mechanism of the p-types SMONs to the reducing gas of NH$_3$ is schematically shown in Fig. 10. When the reducing gas molecules (such as NH$_3$) are adsorbed on the surface of SMONs, the reaction between the NH$_3$ and O$_2^-$ ions will release electrons, which will combine with the holes, resulting in an increase in the Fermi level and reduction of the holes accumulation layer. Consequently, the
conductivity of the SMON layer is decreased. However, for the oxidizing gases, more free electrons are captured from the surface of the p-type SMONs. For example, the NO₂ molecules adsorbed on the sensor surface can capture electrons from the p-type SMONs to form NO₂⁻ as listed in the reaction equation (8). This significantly increases the concentrations of holes carriers, thus resulting the increase in conductivity of the p-type SMONs-based gas sensors. In summary, the resistance of p-type SMONs based sensors will be increased in the presence of the reducing gases, whereas their resistance will be decreased in the presence of the oxidizing gases.

### 2.2.2 Room temperature hydrogen sulfide sensors

At present, the dominant p-type SMONs for RT H₂S gas sensors is CuO, which exhibits excellent sensing performance when operated at RT, especially with the high sensitivity and fast response and recovery. Different from the sensing mechanisms discussed above which are based on the reactions between the target gases with the oxygen ions, the formation of CuS is highly responsible to the sensing response to H₂S at RT.

![Fig. 11. Schematic diagrams of sensing mechanism of CuO: (a) response process in H₂S and (b) recovery process in air. ©2016 American Chemical Society.](image)

Fig. 11 shows schematic diagrams of the sensing mechanism for CuO-based H₂S sensor. H₂S molecules can react with CuO to form CuS on the surface at RT, based on the following reactions.⁹³,²²⁵
\[
\text{H}_2\text{S} \ (g) + \text{CuO} \ (s) \rightarrow \text{CuS} \ (s) + \text{H}_2\text{O} \ (g) \quad (15)
\]
\[
\text{CuS} \ (s) + \text{O}_2 \ (g) \rightarrow \text{CuO} \ (s) + \text{SO}_2 \ (g) \quad (16)
\]

The CuS is a metallic-like conductor. Formation of CuS on the SMON’s surface which will dramatically decrease the resistance of the sensor. Consequently, although the H\(_2\)S is a reducing gas, the response of the sensors exhibits a decrease in resistance. The RT H\(_2\)S gas sensors are highly selective owing to this unique interaction between the H\(_2\)S and CuO. However, their recovery times are relatively long at the RT due to the requirement for the transformation from CuS to CuO.

Fig. 12. (a) Cu 2p\(_{3/2}\) and (b) S 2p XPS spectra of porous CuO nanosheets before and after exposure to H\(_2\)S. 93, © 2016 American Chemical Society.

This H\(_2\)S sensing mechanism has been proved from different studies. For example, Li et al. 93 reported a H\(_2\)S sensor based on porous CuO nanosheets with a thickness about 60 nm on alumina tubes, prepared using a hydrothermal method. The sensor based on these porous CuO nanosheets has an excellent selectivity to H\(_2\)S. It exhibits high response values to H\(_2\)S, but no apparent responses to NH\(_3\), CO, NO, NO\(_2\), H\(_2\), and C\(_2\)H\(_5\)OH 93. The sensor has a superior LOD as low as 10 ppb and a good reproducibility at RT. Sensing mechanism based on the transformation from CuO into CuS on the surface of nanosheets has been verified using the XPS analysis. As the XPS spectra shown in Figs. 12, after the CuO is exposed in H\(_2\)S gas, a new peak of the Cu 2p\(_{3/2}\) at 930.8 eV appears which is attributed to CuS, and the S 2p\(_{3/2}\) and S 2p\(_{1/2}\) states at 162.3 and 163.4 eV can be identified. Similarly, nanostructures of hierarchically flower-like CuO nanostructures 225 have been prepared, and the sensors made of these
nanostructured CuO exhibit high sensitivity, good reproducibility and high sensing selectivity to H$_2$S at RT. Zhang et al. $^{98}$ prepared tube-like CuO nanostructures using pomelo flesh as a bio-template. The unique tube-like CuO nanostructures enhance the diffusion of H$_2$S molecules and promote the rapid fast formation of CuS. The H$_2$S sensor based on the tube-like CuO nanostructures has a good selectivity to H$_2$S, compared to gases such as gasoline, formaldehyde, CH$_4$, H$_2$, acetone, CO, toluene, and ethanol. The response/recovery times are lower than 60 s for the H$_2$S in a wide range of 10 ppb–10 ppm. In addition, the sensor demonstrates a stable detection performance at RT over 3 months.

2.2.3 Room temperature ammonia sensors

Fig. 13. (a) SEM image of network Co$_3$O$_4$ nano-sheet arrays; (b) response/recovery curves of the network Co$_3$O$_4$ nano-sheet arrays based sensor to different concentrations of H$_2$S at room temperature (the inset shows the response value). $^{92}$ © 2016 Elsevier.

The CuO nanostructures are also suitable for NH$_3$ sensing at RT. Sakthivel et al. $^{223}$ fabricated a flexible NH$_3$ sensor on polyethylene terephthalate substrate using CuO nano-rectangles, which were synthesized using a surfactant-free hydrothermal method. The flexible RT sensor made of the CuO nano-rectangles is effective for sensing ammonia even under different bending conditions as it exhibits identical response and response/recovery times. Furthermore, this flexible NH$_3$ sensor exhibits both good stability and reproducibility in a three-month testing period $^{223}$.

Co$_3$O$_4$ nanostructures $^{92}$ have also been found effective for NH$_3$ detection with fast
response speeds at RT. Fig. 13a shows an image of network Co$_3$O$_4$ nano-sheet arrays deposited on an alumina tube prepared using a hydrothermal method. The average sheet thickness of Co$_3$O$_4$ nano-sheet is 39.5 nm. NH$_3$ molecules react with the surface chemisorbed O$_2^-$ ions and form N$_2$ and H$_2$O. As shown in Fig. 13b, the response time for the gas sensor is as short as 9 s for 0.2 ppm NH$_3$ at RT. The sensor responds linearly to the concentrations of NH$_3$ within a range between 1 ppm -100 ppm. It also exhibits a good performance in reproducibility, stability and selectivity to NH$_3$ (compared to H$_2$, CO, H$_2$S and C$_2$H$_5$OH). 3D hierarchical porous Co$_3$O$_4$ nanostructures were synthesized by Wu et al. using polystyrene spheres as the template. The average particle size is 20 nm and the specific surface area is 58.75 m$^2$/g. The structures have macro-size pores, mesopores and plenty of irregular structural defects. The sensor made of these porous Co$_3$O$_4$ nanostructures exhibits a sensitivity of 146% (defined as $(\Delta R/R_g)\times100\%$) to 100 ppm NH$_3$, and has a fast response time of 2 s. However, the recovery time is very long, e.g., longer than 1000 s$^{103}$.

Apart from CuO and Co$_3$O$_4$ nanostructures, the NiO$^{233,240}$ and MnO$_2$$^{239}$ were also used to make the RT NH$_3$ gas sensors, although the response was found to be very slow. Applying special nanostructures can improve the responses of the sensors. For example, the hierarchical hollow nanospheres of α-MnO$_2$ composed of densely aligned nanowires was reported to exhibit an improved NH$_3$ gas sensing sensitivity, and faster response and recovery than the standard α-MnO$_2$ nanowires$^{240}$. Doping with metal ions such as Al doped NiO was also reported as an effective route for improving the sensitivity and responses of the sensor operated at RT$^{233}$.

### 2.2.4 Room temperature nitrogen dioxide sensors

P-type nanostructures have also been reported as good RT NO$_2$ sensing materials. When they are exposed in the oxidizing gases, such as NO$_x$, the NO$_x$ molecules are absorbed on the surface and form NO$_x^-$ and holes, and the reactions of NO$_x$ with the chemisorbed oxygen ions also increase the concentration of holes on the surface, which can be revealed from the reaction equations (17) to (19)$^{234}$. These reactions will widen the width of accumulated hole layer on the surface of p-type SMONs, and cause the
increase of conductivity of the sensors.

\[
\text{NO}_x \text{(gas)} \leftrightarrow \text{NO}_x^- \text{(ads)} + h^+ \quad (17)
\]

\[
\text{NO}_x \text{(gas)} + \text{O}_2^- \text{(ads)} \leftrightarrow \text{NO}_2^- \text{(ads)} + \text{O}^- \text{(ads)} + h^+ \quad (18)
\]

\[
\text{NO}_2 \text{(ads)} + \text{O}_2^- \text{(ads)} \leftrightarrow \text{NO}_3^- \text{(ads)} + 2\text{O}^- \text{(ads)} + h^+ \quad (19)
\]

Self-assembled mesoporous Cu$_3$O virus-like microspheres$^{230}$ exhibited a high response of 28.4 and response/recovery times of 22/42 s to 4 ppm NO$_2$ gas measured at RT. The good sensing performance of this special microstructure is attributed to the formation of hierarchical 3D nanostructures, micropores and large surface area for the effective gas diffusion, the abundant surface oxygen vacancies and the heterojunctions at the interfaces between CuO and Cu$_2$O. The RT NO$_2$ gas sensors were also made using unique chain Co$_3$O$_4$ structures$^{234}$ and self-assembled polycrystalline hexagonal NiO nanosheets$^{226}$. Because of the reduced grain boundaries, which minimizes the carriers’ scattering at the interfaces during the chemisorption of NO$_2$, these special Co$_3$O$_4$ nanostructures showed much better responses to the NO$_2$ than those made of the Co$_3$O$_4$ and NiO nanoparticles.

Apart from detecting H$_2$S, NH$_3$ and NO$_2$, the RT sensors based on the p-type SMONs have also been used for detecting other types of gases. For example, sensor made of MnO$_2$ shows good sensing performance for the acetaldehyde vapor$^{238}$, and at the ambient temperature, β-MnO$_2$ thin film was reported to have good sensing responses and fast response/recovery. The sensitivity was found to be 89% for sensing the 10 ppm acetaldehyde vapor, and the response and recovery times were found to be of 60 s and 11 s, respectively. This sensor has also showed a good selectivity to the acetaldehyde gas, comparing with the other reducing gases such as acetone, benzene, diethylamine, ethanol, dimethylamine, 2-propanol, monomethylamine and ammonia$^{238}$. Sensors made of Co$_3$O$_4$ nanosheets was also reported to have very fast response and recovery of 15/20 s to 50 ppm CO and CH$_4$$^{235}$.

The p-type Cr$_2$O$_3$ based gas sensor is normally operated at higher temperatures above 100 °C, and there are few reports about the Cr$_2$O$_3$ based RT gas sensors. However, 3D cubic mesoporous Cr$_2$O$_3$ nanostructures were recently prepared and the sensor made of this nanostructure exhibits an enhanced sensitivity for detecting ethanol vapor at room
temperature, which is much better than those of the dense Cr$_2$O$_3$ film. The response of the 3D cubic mesoporous Cr$_2$O$_3$ sensor is 13.0 to 1000 ppm ethanol, whereas it is only 2.0 for the dense Cr$_2$O$_3$ film.

Although there are some reports for using the p-type SMONs in gas sensors operated at high temperature, these are much less compared to those of using n-type SMONs. The sensitivity of p-type SMON sensors is generally not as high as that of the n-type SMON sensors. Modification of the p-type SMONs using noble metal nanoparticles or metal ions is an effective route to further enhance the sensing performance, which will be discussed in the Section 3.

3. Room temperature gas sensors based on modified and composite semiconducting metal oxide nanostructures

3.1 Metal modified semiconducting metal oxide and gas sensors

3.1.1 Gas sensors based on noble metal modified semiconducting metal oxide nanostructures

Due to their chemical sensitization and electronic sensitization, noble metals have been widely applied for surface modifications of the SMONs, which has become one of the effective routes to improve their sensing performance, especially for the sensors operated at RT. This can be seen from the comparison of room temperature sensing properties between the pristine and noble metal modified SMONs as listed in Table 3. So far, the noble metals used to modify the SMON based gas sensors are mainly Au$^{242-246}$, Ag$^{247, 248}$, Pt$^{249, 250}$ and Pd$^{251-254}$. Nanoparticles of the noble metals are usually decorated onto surfaces of SMONs using wet-chemical method$^{116}$, thermal vaporization$^{253}$, sputtering method$^{255}$ and electrospinning technology$^{256}$. Many of these sensors have the commonly reported spill-over effect$^{241}$, which means that the active centers on the surface of the solid catalyst produce oxygen active species by adsorbing oxygen molecules. Due to this effect, more the oxygen ions are formed on the surface of the SMONs. Being as excellent active catalysts, noble metal nanoparticles can facilitate the adsorption of oxygen molecules and enhance the formation of oxygen ions by chemical reduction, which then spill onto the surface of
the SMONs, thus increasing the concentration of oxygen ions. The target molecules can also be directly adsorbed onto these noble metal nanoparticles, and then they migrate onto the surface of the SMONs to react with the oxygen ions. These spill-over effects significantly enhance the sensing performance. In addition, these noble metal nanoparticles can also accelerate the transfer of electrons onto the surfaces of the SMONs. Therefore, both the chemical sensitization and electronic sensitization enhance the sensitivity and speed of the SMONs-based sensors.

Table 3 Comparison of room temperature sensing properties of the noble metal modified semiconducting metal oxide nanostructures

<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>Concentration (ppm)</th>
<th>Response value</th>
<th>tres/trec</th>
<th>LOD</th>
<th>Ref.</th>
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<tr>
<td>Au/ZnO</td>
<td>Nanostars</td>
<td>Hydrothermal</td>
<td>CO</td>
<td>50</td>
<td>55.3</td>
<td>10/12 s</td>
<td>5 ppm</td>
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<td>ZnO</td>
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<td>1000</td>
<td>0</td>
<td>10/12 s</td>
<td>-</td>
<td>-</td>
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<td>Pt/ZnO</td>
<td>Nanowires</td>
<td>Vapor-liquid-solid</td>
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<td>1.02</td>
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<tr>
<td>ZnO</td>
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<td></td>
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<td>120/180 s</td>
<td>-</td>
<td>-</td>
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<tr>
<td>Au/ZnO</td>
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<td>Hydrothermal</td>
<td>H₂S</td>
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<td>79.4</td>
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<td>ZnO</td>
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<td></td>
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<td>~170 s</td>
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<td>Au/ZnO</td>
<td>Nanorods</td>
<td>Vapor phase transport</td>
<td>H₂S</td>
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<td>11/20 min</td>
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<td>~475</td>
<td>10/13 min</td>
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<td>Sol-gel</td>
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<td>Core-shells</td>
<td>Sol-gel</td>
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<td>332/736 s</td>
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<td>9</td>
<td>30/30 s</td>
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<td>30/30 s</td>
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<td>Sol-gel</td>
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<td>4.35</td>
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<td>Nanofibers</td>
<td>Electrospinning</td>
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<td>6.97</td>
<td>3/150 s</td>
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<td>6.97</td>
<td>-</td>
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<td>Sol-gel</td>
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<td>Shell</td>
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<td>Thin films</td>
<td>Magnetron sputtering</td>
<td>CH₄</td>
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<td>18.2⁰</td>
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<td>18.2⁰</td>
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<td>Deposition Method</td>
<td>Deposition Gas</td>
<td>Concentration (ppm)</td>
<td>Response Time/Recovery Time</td>
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</tbody>
</table>

Notes:
- $C =$ concentration;
- $t_{res}/t_{rec} =$ response time/recovery time;
- LOD = limit of detection;
- Response is defined as $R_a/R_g$ (for reducing gases) or $R_g/R_a$ (for oxidizing gases), $R_a$: resistance of the sensor exposed to reference, $R_g$: resistance of the sensor exposed to target:
  - * Here the response is defined as $\Delta R/R_g$ (for reducing gases) or $\Delta R/R_a$ (for oxidizing gases), $\Delta R$: the change in resistance.
  - # Here the response is defined as $(\Delta R/R_g) \times 100\%$ (for reducing gases) or $(\Delta R/R_a) \times 100\%$ (for oxidizing gases).
At RT, some gases such as CO and H$_2$ are very difficult to be detected using the sensors made of the pristine SMONs. However, this problem might be solved by modifying the surface of these SMONs using noble metal nanoparticles. For example, Arunkumar et al.\textsuperscript{113} prepared ZnO nanostar features using a hydrothermal route and then decorated these nanostars using Au nanoparticles with an average size of $\sim$5-6 nm as shown in Fig. 14a. The ZnO nanostars decorated with 3 wt% gold nanoparticles can enhance the response ($\sim$15 for 50 ppm CO) and achieve very fast response/recovery times ($\sim$8/15 s) at 35 °C\textsuperscript{113}. The selectivity of the sensor for Co sensing is excellent against the other interfering gases including methanol, ethanol, acetone and hydrogen. Fig. 14b shows the energy band diagrams of ZnO and Au/ZnO nanostars before and after CO exposure. Due to the spillover effect, a nanoscale depletion region is formed at the interface between Au nanoparticles and ZnO as a result of strong electronic interactions, thus altering the height of Schottky barrier. Therefore, the enhanced performance of the sensor operated at RT is attributed to the spillover effect\textsuperscript{113}.

Choi et al.\textsuperscript{114} grew a network of ZnO nanowires using a vapor-liquid-solid method and then these nanowires were functionalized with Pd nanodots using a $\gamma$-ray radiolysis method, and the sensor made of these decorated nanowires shows an improvement of the sensing performance. This improvement is attributed to the electronic and chemical
sensitizations from the Pd nanodots. Wang et al. reported a highly sensitive RT CO sensor based on Pt/SnO₂ porous nanostructures. The porous SnO₂ nanostructures were synthesized using a solvothermal method, and Pt nanoparticles were then decorated onto the SnO₂ using hexachloro-platinic acid. The sensor exhibits a good response with a value of 64.5 to 100 ppm CO at RT. It also shows a good selectivity, compared to the other gases including CO, H₂, Ni(CH₃)₃, NH₃ and CH₄. Similarly, a RT CO gas sensor made of Au/In₂O₃ composite nano-rods was fabricated, and showed a high response and fast response/recovery times (30/30 s to 100 ppm CO).

Fig. 15. (a) Responses of nanosensor based on single Pd/ZnO nanowires with different diameters to 100 ppm of H₂ at RT and 30% RH (the inset shows the schematic of the nanosensor device structure); (b) response of Pd/ZnO nanowires based sensor to 100 ppm of H₂ at 30% and 70% RH at RT. © 2018 Elsevier. (c) TEM image of 30 at% Pd/SnO₂ nanofiber; (d) the response/recovery curves of 30 at% Pd/SnO₂ nanofiber based sensor for H₂ gas. © 2010 Elsevier.

Modification of SMONs by noble metals can not only enhance the sensitivity, but also significantly improve the selectivity and response/recovery speed. For example, ZnO nanowire-based sensor modified with Pd nanoparticles exhibits both ultra-high sensitivity and very fast response and recovery. A Pd-modified ZnO nanowire-based RT nanosensor was prepared using electrochemical deposition by Lupan et al.
and it exhibits very fast response/recovery times of 6.4/7.4 s and a super-high response value of 13100 to 100 ppm H₂ as shown in Figs. 15a and 15b. This H₂ sensor shows a very good selectivity against the other gases such as CO, CH₄, ethanol and acetone. The sensor can be operated with very low current levels at an ultra-low power consumption.

Ultra-sensitive RT hydrogen gas sensors based on noble metal modified SnO₂ have also been reported. For example, the sensor based on Pt/SnO₂ nanoparticles exhibits a super-high response (e.g., 10500 to 1000 ppm H₂) at RT. ²⁴⁹ Lee et al. ²⁵³ reported a RT hydrogen sensor made of Pd/SnO₂ nanowires (as shown in Fig. 15c) prepared using a thermal evaporation method, and the sensor shows an ultra-high sensitivity of about 120000% (defined as (ΔR/Rg)×100%) to 10000 ppm H₂ and a fast response time of 2 s as shown in Fig. 15d. The Pd/SnO₂ nanofibers were also synthesized using an electrospinning method, and the sensor made of these nanofibers exhibits a super-fast response/recovery times to H₂ (4/3 s to 1000 ppm H₂) and an ultra-low LOD of 20 ppb. The response of a sensor made of Pt/TiO₂ nanocomposites to 1000 ppm H₂ in N₂ was also reported as high as 6000 at RT, with short response/recovery times of only 10/20 s. ²⁶⁷

![Fig. 16. (a) SEM image of Au/ZnO nanorods; (b) response/recovery curves of the Au/ZnO nanorods-based sensor and pristine ZnO nanorods-based sensor to 3 ppm H₂S at room temperature; (c) responses of Au/ZnO nanorods-based sensor and pure ZnO nanorods-based sensor to different gases. ²⁵⁷, © 2015 Elsevier.](image)

Apart from the chemical sensitization and electronic sensitization, there are other mechanisms to enhance the sensing performance of the SMONs. For example, the formation of nano-scale Schottky type junctions between Au nanoparticles and ZnO
nanorods and Au sulfidation with high concentrations of H$_2$S. Hosseini et al. prepared ZnO nanorods using a vapor phase transport method, and found that H$_2$S sensing performance has been significantly enhanced at RT after the modification of the surface of ZnO nanorods with Au nanoparticles (see Fig. 16a). As shown in Figs. 16b and 16c, both high response (1270 to 6 ppm of H$_2$S) and good H$_2$S selectivity of the Au/ZnO nanorods have been achieved, which are much better than those of the pristine ZnO nanorods.

In summary, due to the combined effects of chemical sensitization and electronic sensitization, noble metal nanoparticles and other nanostructures are suitable to be used to modify the SMONs in order to improve the sensing performance of the RT gas sensors. One significant improvement is the shortening of the response and recovery times, along with the enhanced response values and selectivity.

### 3.1.2 Gas sensors based on conventional metal ion doped semiconducting metal oxide nanostructures

Doping of metal ions in the SMONs can increase the number of active sites and defects on the surface of SMON nanocrystals, thus enhance the amount of oxygen species and increase the adsorbed gas molecules on the sensor’s surface. Therefore, the gas sensing performance of the SMONs can be effectively improved by doping of metal ions including Al$^{3+}$, Cu$^{2+}$, Zn$^{2+}$, Ni$^{2+}$, Co$^{3+}$, Fe$^{3+}$, Mg$^{2+}$, and Sb$^{5+}$. The recent key sensing applications of RT gas sensors using this method are summarized in Table 4.

<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>$t_{res}/t_{rec}$</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Al/NiO</td>
<td>Nanosheets</td>
<td>Solvent-thermal</td>
<td>NO$_2$</td>
<td>10</td>
<td>2.77*</td>
<td>50/200 s</td>
<td>250 ppb</td>
<td>117</td>
</tr>
<tr>
<td>Sb/WO$_3$</td>
<td>Nanoparticles</td>
<td>Chemical solution</td>
<td>NO$_2$</td>
<td>10</td>
<td>51</td>
<td>~150/~200 s</td>
<td>~1 ppm</td>
<td>209</td>
</tr>
<tr>
<td>Cu/Cu$_2$O</td>
<td>Hollow spheres</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>10</td>
<td>6.27</td>
<td>34/- s</td>
<td>-</td>
<td>282</td>
</tr>
<tr>
<td>Cu/ZnO</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>20</td>
<td>31.1*</td>
<td>15/48 s</td>
<td>~10 ppm</td>
<td>118</td>
</tr>
<tr>
<td>Sb/SnO$_2$</td>
<td>Nanoparticles</td>
<td>Sol-gel</td>
<td>NH$_3$</td>
<td>50</td>
<td>4316*</td>
<td>70/- s</td>
<td>-</td>
<td>283</td>
</tr>
</tbody>
</table>

Table 4 Summary of room temperature sensors made of metal ion doped semiconducting metal oxide nanostructures and their sensing properties
<table>
<thead>
<tr>
<th>System</th>
<th>Type</th>
<th>Growth Method</th>
<th>Media</th>
<th>C</th>
<th>t_res/t_rec</th>
<th>LOD</th>
<th>Response</th>
</tr>
</thead>
<tbody>
<tr>
<td>Zn/NiO</td>
<td>Dendritic</td>
<td>Electrolytic</td>
<td>NH₃</td>
<td>30</td>
<td>0.2°</td>
<td>5/30 s</td>
<td>5 ppm</td>
</tr>
<tr>
<td>Mg/ZnO</td>
<td>Thin films</td>
<td>Spray pyrolysis</td>
<td>NH₃</td>
<td>100</td>
<td>769</td>
<td>34/28 s</td>
<td>~1 ppm</td>
</tr>
<tr>
<td>Ce₀.₉₄(Zn₀.₆O₂</td>
<td>Nanosheets</td>
<td>Sol-hydrothermal</td>
<td>NH₃</td>
<td>100</td>
<td>87</td>
<td>-</td>
<td>100 ppm</td>
</tr>
<tr>
<td>Cu/Cu₂O₄</td>
<td>Nanoplatelets</td>
<td>Hydrothermal</td>
<td>NH₃</td>
<td>400</td>
<td>7.9°</td>
<td>~14 min</td>
<td>~25 ppm</td>
</tr>
<tr>
<td>Fe/WO₃</td>
<td>Microspheres</td>
<td>Spray pyrolysis</td>
<td>Ethanol</td>
<td>400</td>
<td>~140</td>
<td>~10/~40 s</td>
<td>~100 ppm</td>
</tr>
<tr>
<td>Al/ZnO</td>
<td>Hexagonal facets</td>
<td>Sol-gel</td>
<td>Ethanol</td>
<td>300</td>
<td>94°</td>
<td>68/50 s</td>
<td>-</td>
</tr>
<tr>
<td>Co/TiO₂</td>
<td>Nanoparticles</td>
<td>Sol-gel</td>
<td>Ethanol</td>
<td>500</td>
<td>~105°</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td>SnO₂::Sb</td>
<td>Nanowires</td>
<td>CVD</td>
<td>Ethanol</td>
<td>300</td>
<td>1.3</td>
<td>10/87 s</td>
<td>40 ppm</td>
</tr>
<tr>
<td>Na/ZnO</td>
<td>Nanoflowers</td>
<td>Solution route</td>
<td>Acetone</td>
<td>100</td>
<td>3.35</td>
<td>18/63 s</td>
<td>0.2 ppm</td>
</tr>
<tr>
<td>Ni/ZnO</td>
<td>Nanorods</td>
<td>Electrodeposition</td>
<td>Acetone</td>
<td>100</td>
<td>1.6</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td>Sb/SnO₂</td>
<td>Nanoribbons</td>
<td>Thermal evaporation</td>
<td>H₂S</td>
<td>100</td>
<td>~18</td>
<td>~500/~500 s</td>
<td>100 ppb</td>
</tr>
<tr>
<td>Zn/ZnO</td>
<td>Nanotetrapods</td>
<td>Thermal evaporation</td>
<td>H₂S</td>
<td>4</td>
<td>38°</td>
<td>~200/~1000 s</td>
<td>1 ppm</td>
</tr>
<tr>
<td>Zn/In₂O₃</td>
<td>Nanowires</td>
<td>CVD</td>
<td>CO</td>
<td>5</td>
<td>~57°</td>
<td>20/10 s</td>
<td>~1 ppm</td>
</tr>
<tr>
<td>SnO₂::Sb</td>
<td>Nanoporous films</td>
<td>Sol-gel</td>
<td>Cl₂</td>
<td>3</td>
<td>500°</td>
<td>60/120 s</td>
<td>~1 ppm</td>
</tr>
<tr>
<td>Mg/ZnO</td>
<td>Nanorods</td>
<td>Frequency sputtering</td>
<td>H₂</td>
<td>200</td>
<td>30</td>
<td>85/70 s</td>
<td>-</td>
</tr>
<tr>
<td>Mg/ZnO</td>
<td>Film</td>
<td>Rf sputtering</td>
<td>H₂</td>
<td>200</td>
<td>35-40</td>
<td>75/54 s</td>
<td>-</td>
</tr>
<tr>
<td>Cd/ZnO</td>
<td>Nanowires</td>
<td>Electrodeposition</td>
<td>H₂</td>
<td>100</td>
<td>274°</td>
<td>14/11 s</td>
<td>-</td>
</tr>
<tr>
<td>Al/ZnO</td>
<td>Nanowires</td>
<td>Electrodeposition</td>
<td>Ethanol</td>
<td>1000</td>
<td>1.7</td>
<td>10/30 s</td>
<td>-</td>
</tr>
<tr>
<td>Co/TiO₂</td>
<td>Mesoporous</td>
<td>Self-assembly</td>
<td>H₂</td>
<td>1000</td>
<td>4082</td>
<td>66/- s</td>
<td>50 ppm</td>
</tr>
<tr>
<td>Nb/TiO₂</td>
<td>Nanotubes</td>
<td>Annealing</td>
<td>H₂</td>
<td>1000</td>
<td>30,9°</td>
<td>100/- s</td>
<td>-</td>
</tr>
</tbody>
</table>

Notes:
- C = concentration;
- t_res/t_rec = response time/recovery time;
- LOD = limit of detection;
- Response is defined as Ra/Rg (for reducing gases) or Rg/Ra (for oxidizing gases). Ra: resistance of the sensor exposed to reference, Rg: resistance of the sensor exposed to target;
- * Here the response is defined as ΔR/Rg (for reducing gases) or ΔR/Ra (for oxidizing gases), ΔR: the change in resistance.
- # Here the response is defined as (ΔR/Rg)×100% (for reducing gases) or (ΔR/Ra)×100% (for oxidizing gases).
Fig. 17. (a) Responses of sensors made of 2%-Sb-WO$_3$, 2%-Ce-WO$_3$ and 2%-Cd-WO$_3$ to different concentration of NO$_2$; (b) responses of sensors made of 2%-Sb-WO$_3$ to different gases. © 2017 American Chemical Society.

The amount of dopant Al$^{3+}$ ions was found to significantly affect the gas sensing properties of NiO nanosheets. Al$^{3+}$ doped NiO nanosheets have introduced many new oxygen vacancies due to aliovalent ion doping. Superoxide complexes such as Ni$^{2+}$-O$_2^-$ are easily formed on the surface of the NiO due to the existence of oxygen vacancies. As they are very active, they can significantly increase the sensitivity of the NiO nanosheets. Compared with those of the pure NiO nanosheets, the response to NO$_2$ for the Al doped NiO nanosheets based sensor to NO$_2$ was enhanced up to 35 times at RT. Doping with metal ions including Sb, Cd, and Ce have also been proved to enhance the sensing properties of the WO$_3$ nanoparticles to NO$_2$ gas at RT. Among these, Sb-doped WO$_3$ nanoparticles exhibit a 6.8 times higher response and a much better selectivity than those of the undoped WO$_3$ (as shown in Figs. 17). The enhancement mechanisms have been identified to be the increase in the number of oxygen vacancies on the surface of metal doped WO$_3$ based on the analysis results from photoluminescence, Raman spectroscopy and XPS.

The responses and recovery speeds of the sensor can be significantly improved by doping of metal ions into the SMONs, which is important for the practical applications of the RT gas sensors. For example, Zn-doped NiO dendritic nanostructure exhibits faster responses (5-8 times) and faster recovery (30-50 times) rates than those of the pure NiO dendritic crystals. Sensor based on Mg-doped ZnO thin films on glass substrates deposited through spray pyrolysis process shows a much higher response.
(796 towards 100 ppm of NH₃) and faster response/recovery speeds (34/28 s) than those of the pure ZnO film measured at RT. The sensor based on Sb doped SnO₂ nanowires prepared using a chemical vapor deposition (CVD) method shows a typical p-type behavior, and a fast response time of about 10 s to 300 ppm ethanol at RT.

Fig. 18. (a) Schematic diagrams of the NH₃ reaction mechanism on the surface of Ce₀.₉₄Zr₀.₀₆O₂ nano-sheets; (b) TEM image of porous Ce₀.₉₄Zr₀.₀₆O₂ nano-sheets; (c) response/recovery curves of the porous Ce₀.₉₄Zr₀.₀₆O₂ nanosheets based sensor to NH₃. © 2018 Elsevier.

Adsorption of water vapor on the SMONs surfaces is sometimes enhanced by metal ions doping, which seems a bad news for a gas sensor. However, for RT NH₃ gas sensors, this is especially beneficial as the NH₃ molecules react with the absorbed H₂O to form the NH₄⁺ and OH⁻ as is schematically shown in Fig. 18a. The electrolytic conductivity of NH₄⁺ and OH⁻ can significantly improve the sensitivity of sensors at RT. Porous Ce₀.₉₄Zr₀.₀₆O₂ nano-sheets (see Fig. 18b) with an average thickness of 8 nm was prepared using a sol-hydrothermal process. Doping of Zr⁴⁺ ions into the CeO₂ nanosheets enlarges the specific surface areas (185.₄m²/g) and increases the pore volumes (0.₅₁ cm³/g). These modifications result in a much higher sensitivity (e.g. 87 to 100 ppm NH₃) at RT (see Fig. 18c), better selectivity and a very low LOD of 100 ppb.

The H₂ sensors made of metal ion doped SMONs were reported to exhibit high responses, although their response/recovery times were also reported to be longer than
those made of the noble ions modified SMONs-based RT H\textsubscript{2} gas sensors\textsuperscript{278, 280, 289, 291}.

For examples, Co-doped TiO\textsubscript{2} sensors exhibit an ultra-high response with a value of 4082 to 1000 ppm H\textsubscript{2} gas, although the response time is 66 s, which is quite slow for detection of highly explosive H\textsubscript{2}\textsuperscript{278}.

In summary, compared to those sensors made of noble metal nanoparticle modified SMONs, the improved effects of gas sensors made of the metal ions modified SMONs are not as significant. However, the SMONs can be modified simultaneously by both metal ions and noble metal nanoparticles, which will combine the advantages of both metal ions and noble metal nanoparticles.

3.2 Composites of semiconducting metal oxide nanostructures and gas sensors

3.2.1 Mechanism for enhanced sensing performance

The RT gas sensing performance of the SMONs operated at RT can be improved by integrating them with other metal oxides or carbon nanomaterials. For example, heterojunctions can be formed at the interfaces of different metal oxides or at the interfaces between SMONs and carbon nanomaterials, as schematically illustrated in Fig. 19. At the p-n heterojunctions between p-type and n-type SMONs, the electrons at the conduction band states of n-type SMONs will transfer to the lower energy valence band states of p-type SMONs across the interface. Thus, a depletion layer will form at the p-n heterojunction due to recombination of electrons and holes.

For the n-n heterojunction, the electrons will be transported at the interfaces between different materials due to their differences of their conduction band states. As a result, a depletion layer forms at the surface of n-type SMONs with higher-energy conduction band states due to the loss of electrons. At the same time, an accumulation layer forms at the surface of n-type SMONs with lower-energy conduction band states due to the accumulation of electrons.

For the p-p heterojunction, the major charge carriers are holes. Due to the differences of valence band energies of different SMONs, the charge carriers are transported from one p-type SMON (which has a higher energy valence band state) to the other p-type
SMON (which has a lower-energy valence band state). Therefore, there are hole depletion region formed at the surface of the first SMONs (with higher energy valence band state) and the hole accumulation region forms at the surface of the second SMONs (with a lower energy valance band state) as shown in Fig. 19.

Fig. 19. Schematic illustrations of the energy band structures at heterojunction interfaces of different types of heterojunctions. (a) p-n junction, (b) n-n junction and (c) p-p junction.

These formed heterojunctions can effectively accelerate the transport of electrons. On the other hand, these heterojunctions can also enhance oxygen adsorption, therefore, abundant oxygen vacancies are formed on the surfaces of the SMONs composites, which can provide new active sites for sensing reaction. In addition, the composites of SMONs often contain numerous mesopores, which are beneficial to the adsorption and desorption of gas molecules. All of these effects will improve the sensitivity and
response rates of the RT gas sensors made of composites of the SMONs.

### 3.2.2 Gas sensors based on composites of semiconducting metal oxide nanostructures and other metal oxides

Composite oxides of the SMONs have been proposed to combine two or more semiconducting metal oxides together to enhance the gas sensing performance at RT. The examples of composites include: n-type SMONs with n-type SMONs (e.g. Fe$_2$O$_3$/ZnO$^{292}$, ZnO/SnO$_2$$^{293}$, In$_2$O$_3$/SnO$_2$$^{134,294}$), p-type SMONs with n-type SMONs (e.g. NiO-ZnO$^{120}$, CuO/TiO$_2$$^{121}$, In$_2$O$_3$/CuO$^{122}$, NiO/WO$_3$$^{295}$) and p-type SMONs with p-type SMONs (e.g. Cu$_2$O/Co$_2$O$_4$$^{296}$ and NiO/CuO$^{131}$). In addition, the composite formed by integrating the SMONs with non-semiconductor metal oxide (e.g. K$_2$O/In$_2$O$_3$$^{129}$ and CaO/SnO$_2$$^{251}$) have also been reported.

Table 5 summarizes the recently reported RT gas sensors made of composite oxides of the SMONs and/or other metal oxides. For these composite oxides, a number of oxygen vacancies are formed on both the surfaces and interfaces, which provides many active sites for the gas sensing reactions. Plenty of defects will also be formed at the interfaces of nanostructures in different metal oxides nanoparticles. In addition, the heterojunctions are usually formed at the interfaces of different metal oxides, which can effectively accelerate the electron transfer between different particles, thus accelerating the response speed of the sensor. Besides, the composite oxides often contain lots of mesoporous structures due to the accumulation of nanoparticles, which are beneficial to the adsorption and desorption of gas molecules. These factors can improve the sensing performance of the sensor made of these composite oxides, especially for the sensitivity and response speed. Most sensors made of the composite oxides exhibit very fast response times at RT. For examples, the gas sensor based on nanocomposite of CuO/TiO$_2$$^{121}$ shows a very fast response time of 2 s at RT, and the sensor based on plate-like NiO/WO$_3$ nanocomposites$^{295}$ exhibits excellent sensitivity and ultrafast response/recovery times (2.5/1.1 s) to NO$_2$ at RT.

Table 5 Room temperature sensing properties of composite of semiconducting metal oxide nanostructures and other metal oxides
<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>$t_{res}/t_{rec}$</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>NiO/ZnO</td>
<td>Nanocones</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>50</td>
<td>42$^a$</td>
<td>27/150 s</td>
<td>~15 ppm</td>
<td>120</td>
</tr>
<tr>
<td>CuO/TiO$_2$</td>
<td>Nanoparticles</td>
<td>Sol-gel</td>
<td>NH$_3$</td>
<td>50</td>
<td>97$^a$</td>
<td>2/55 s</td>
<td>~5 ppm</td>
<td>121</td>
</tr>
<tr>
<td>In$_2$O$_3$/CuO</td>
<td>Nanofibers</td>
<td>Electrospinning</td>
<td>NH$_3$</td>
<td>100</td>
<td>1.9$^*$</td>
<td>2/- s</td>
<td>0.3 ppm</td>
<td>122</td>
</tr>
<tr>
<td>Silica/Co$_2$</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>100</td>
<td>135$^g$</td>
<td>120/600 s</td>
<td>20 ppm</td>
<td>298</td>
</tr>
<tr>
<td>Fe$_3$O$_4$/ZnO</td>
<td>Nanorods</td>
<td>Sol-gel</td>
<td>NO$_2$</td>
<td>10</td>
<td>440</td>
<td>300/- s</td>
<td>5 ppm</td>
<td>293</td>
</tr>
<tr>
<td>Cr$_2$O$_3$/ZnO</td>
<td>Thick film</td>
<td>Screen-printing</td>
<td>NO$_2$</td>
<td>10</td>
<td>2.5/1.1 s</td>
<td>-</td>
<td>5 ppm</td>
<td>295</td>
</tr>
<tr>
<td>CuO/MnO$_2$</td>
<td>Flower/sheets</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>100</td>
<td>350</td>
<td>20/- s</td>
<td>100 ppm</td>
<td>299</td>
</tr>
<tr>
<td>ZnO/SnO$_2$</td>
<td>Thin film</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>20</td>
<td>11.1</td>
<td>-</td>
<td>-</td>
<td>293</td>
</tr>
<tr>
<td>NiO/WO$_3$</td>
<td>Plates</td>
<td>Annealing</td>
<td>NO$_2$</td>
<td>30</td>
<td>4.8</td>
<td>2.5/1.1 s</td>
<td>5 ppm</td>
<td>120</td>
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<tr>
<td>CuO/SnO$_2$</td>
<td>Rod-like</td>
<td>Electrospinning</td>
<td>NO$_2$</td>
<td>60</td>
<td>7.5$^*$</td>
<td>-</td>
<td>~5 ppm</td>
<td>123</td>
</tr>
<tr>
<td>In$_2$O$_3$/SnO$_2$</td>
<td>Nanorods</td>
<td>Electrospinning</td>
<td>NO$_2$</td>
<td>100</td>
<td>4.67</td>
<td>14/22 s</td>
<td>3 ppm</td>
<td>294</td>
</tr>
<tr>
<td>In$_2$O$_3$/TiO$_2$</td>
<td>Nanofibers</td>
<td>Electrospinning</td>
<td>NO$_2$</td>
<td>100</td>
<td>4.8</td>
<td>15/- s</td>
<td>10 ppm</td>
<td>294</td>
</tr>
<tr>
<td>Al$_2$O$_3$/TiO$_2$</td>
<td>Nanotubes</td>
<td>Induction</td>
<td>NO$_2$</td>
<td>97</td>
<td>1000</td>
<td>8/- s</td>
<td>0.97 ppm</td>
<td>301</td>
</tr>
<tr>
<td>K$_2$O/In$_2$O$_3$</td>
<td>Nanowires</td>
<td>Template</td>
<td>NO$_2$</td>
<td>97</td>
<td>151.78$^e$</td>
<td>12/- s</td>
<td>48.5 ppm</td>
<td>129</td>
</tr>
<tr>
<td>NiO/SnO$_2$</td>
<td>Nanosheets</td>
<td>Annealing</td>
<td>NO$_2$</td>
<td>60</td>
<td>~7.5$^*$</td>
<td>-</td>
<td>~5 ppm</td>
<td>302</td>
</tr>
<tr>
<td>SnO$_2$/NiO</td>
<td>Thin film</td>
<td>RF sputtering</td>
<td>H$_2$S</td>
<td>10</td>
<td>440</td>
<td>-</td>
<td>100 ppb</td>
<td>293</td>
</tr>
<tr>
<td>Cu$_2$O/Co$_3$O$_4$</td>
<td>Heteroarrays</td>
<td>Electrodeposition</td>
<td>H$_2$S</td>
<td>20</td>
<td>~2600</td>
<td>~100/-100 s</td>
<td>~0.1 ppm</td>
<td>296</td>
</tr>
<tr>
<td>NiO/CuO</td>
<td>flower-like</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>100</td>
<td>77.16$^g$</td>
<td>2 s/-</td>
<td>1 ppm</td>
<td>131</td>
</tr>
<tr>
<td>NiO/In$_2$O$_3$</td>
<td>Nanofibers</td>
<td>Electrospinning</td>
<td>H$_2$S</td>
<td>3</td>
<td>14/22</td>
<td>15/- s</td>
<td>10 ppm</td>
<td>303</td>
</tr>
<tr>
<td>SnO$_2$/CuO</td>
<td>Heterojunctions</td>
<td>Screen printing</td>
<td>H$_2$S</td>
<td>1</td>
<td>3672$^f$</td>
<td>15/- s</td>
<td>10 ppm</td>
<td>304</td>
</tr>
<tr>
<td>CuO/ZnO</td>
<td>Nanorods</td>
<td>Pulsed laser</td>
<td>H$_2$S</td>
<td>0.5</td>
<td>25$^g$</td>
<td>180/15 s</td>
<td>~0.5 ppm</td>
<td>305</td>
</tr>
<tr>
<td>In$_2$O$_3$/ZnO</td>
<td>Core-shells</td>
<td>Hydrothermal</td>
<td>H$_2$S</td>
<td>100</td>
<td>925$^g$</td>
<td>-</td>
<td>20 ppm</td>
<td>306</td>
</tr>
<tr>
<td>α-Fe$_2$O$_3$/ZnO</td>
<td>Nanowires</td>
<td>Piezo-surface</td>
<td>Ethanol</td>
<td>700</td>
<td>706.8$^g$</td>
<td>-</td>
<td>~100 ppm</td>
<td>307</td>
</tr>
<tr>
<td>ZnO/CuO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>Alcohol</td>
<td>20</td>
<td>3.32</td>
<td>62/83 s</td>
<td>~150 ppm</td>
<td>308</td>
</tr>
<tr>
<td>VO$_2$/ZnO</td>
<td>Heteronanostreamuctures</td>
<td>Heteroepitaxial</td>
<td>Acetone</td>
<td>100</td>
<td>4.51</td>
<td>8/18 s</td>
<td>~10 ppm</td>
<td>309</td>
</tr>
<tr>
<td>CuO/ZnO</td>
<td>Thick film</td>
<td>Screen-printing</td>
<td>Cl$_2$</td>
<td>300</td>
<td>195$^a$</td>
<td>18/50 s</td>
<td>-</td>
<td>310</td>
</tr>
<tr>
<td>ZnO/SnO$_2$</td>
<td>Heterojunctions</td>
<td>Hydrothermal</td>
<td>Ozone</td>
<td>0.06</td>
<td>12</td>
<td>13/90 s</td>
<td>20 ppb</td>
<td>311</td>
</tr>
<tr>
<td>NiO/Nb$_2$O$_5$</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>150</td>
<td>1.68</td>
<td>100.42/524.84 s</td>
<td>-</td>
<td>312</td>
</tr>
<tr>
<td>Cr$_2$O$_3$/Nb$_2$O$_5$</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>200</td>
<td>5.24</td>
<td>40/- s</td>
<td>-</td>
<td>313</td>
</tr>
</tbody>
</table>

Notes:
\[ C = \text{concentration}; \]
\[ \frac{t_{\text{res}}}{t_{\text{rec}}} = \text{response time}/\text{recovery time}; \]
\[ \text{LOD} = \text{limit of detection}; \]

Response is defined as \( Ra/R_g \) (for reducing gases) or \( R_g/R_a \) (for oxidizing gases), \( Ra \): resistance of the sensor exposed to reference, \( R_g \): resistance of the sensor exposed to target:

* Here the response is defined as \( \Delta R/R_g \) (for reducing gases) or \( \Delta R/R_a \) (for oxidizing gases), \( \Delta R \): the change in resistance.

# Here the response is defined as \( (\Delta R/R_g) \times 100\% \) (for reducing gases) or \( (\Delta R/R_a) \times 100\% \) (for oxidizing gases).

Fig. 20. (a) TEM and (b) HRTEM images of mesoporous \( \text{In}_2\text{O}_3/\text{CuO} \) composite multijunction nanofibers, (c) response values and times of the sensor to different concentrations of \( \text{NH}_3 \). \(^{122}\) © 2018 Elsevier. (d, e) TEM images of composite of \( \text{In}_2\text{O}_3/\text{SnO}_2 \) nanorod heterostructures; (f) response/recovery curves of the sensor to different concentration of \( \text{NO}_x \). \(^{134}\) © 2015 The Royal Society of Chemistry.

The composite of mesoporous \( \text{In}_2\text{O}_3/\text{CuO} \) multijunction nanofibers \(^{122}\) was prepared using an electrospinning method by Zhou \textit{et al.} The composite is composed with the \( \text{In}_2\text{O}_3 \) nanoparticles and \( \text{CuO} \) nanoparticles (with a molar ratio of \( \text{Cu:In} \) of 100:5). The TEM images shown in Figs. 20a and 20b indicate that the composite has many mesoporous structures with diameters from 1.9 to 22.9 nm and large specific surface areas (48.7 m\(^2\)/g). The \( \text{In}_2\text{O}_3 \) nanoparticles are surrounded by the \( \text{CuO} \) nanoparticles to form numerous p-p homojunctions and p-n heterojunctions \(^{122}\). XPS analysis indicates that the ratio of oxygen defect/vacancy on its surface is as high as 45.4%. Due to the
existence of larger specific and mesoporous surface areas and the availability of chemisorbed oxygen and the formation of heterojunctions, the sensor has a much higher response to NH$_3$ than those of a CuO nanostructured sensor. The response time is also very short with a value lower than 8 s for NH$_3$ from 0.3 to 100 ppm (see Fig. 20c). The selectivity and LOD are also significantly improved due to the addition of In$_2$O$_3$.

Xu et al. 134 prepared composites of In$_2$O$_3$/SnO$_2$ nanorod heterostructures (see Figs. 20d and 20e) using the electrospinning to improve the oxygen deficiency and carrier density of the SnO$_2$. The SnO$_2$ nanoparticles are distributed along with the In$_2$O$_3$ to form numerous heterojunctions and defects at their interfaces. The availability of oxygen vacancies on the surface and at the interface has been verified using XPS 134. Compared with pure SnO$_2$ nanorods, In$_2$O$_3$/SnO$_2$ nanorods (with the atom ratio of 25:0.3 of Sn:In) exhibit 11 times higher response to NO$_x$ with a very faster response time of 4.67 s and a lower LOD with a value of 0.1 ppm (see Fig. 20f).

NiO/CuO nanocomposites with the NiO:CuO molar ratio of 1:1 have been synthesized using a hydrothermal method 131, and the nanocomposites are consisted of CuO nanoparticles and NiO nanoplates with lots of mesoporous structures. The p-p heterojunctions formed at the interfaces of NiO and CuO accelerates the electron transfers from NiO to CuO, thus resulting in a faster response. The mesoporous hierarchical nanostructures with much larger surface areas facilitate effective adsorption and desorption of gas molecules on the surface. Thus, it exhibits an ultra-fast response speed (2 s to 100 ppm NO$_2$) to NO$_2$ at RT.
Fig. 21. (a) Response histogram of SnO₂/NiO thin film-based room temperature gas sensor to different gases; (b) response values of the SnO₂/NiO thin film-based RT gas sensor to different concentration of H₂S; (c) response/recovery curve to 100 ppm H₂S. 123, © 2017 Elsevier. (d) TEM image of 8% silica-CeO₂; (e) response/recovery curves of the pure CeO₂-based sensor to NH₃; (f) response/recovery curves of the 8% silica-CeO₂-based sensor to NH₃. 198, © 2017 Elsevier.

Kaur et al. 123 prepared a SnO₂/NiO thin film using a sputtering method and then fabricated a RT H₂S sensor. As shown in Fig. 21a, the sensor exhibits a high response with a value of 440 to 10 ppm H₂S, which is 9 and 415 times higher than those made of pure SnO₂ and NiO films, respectively. Selectivity has also been improved using the SnO₂/NiO thin film (see Fig. 21b). The formation of p-n heterojunctions using the p-type NiO and n-type SnO₂ semiconductors apparently changes the resistance of the composite film. The enhanced response of SnO₂:NiO nanocomposite sensor is mainly due to the modifications of p-n junctions resulted from the conversion of NiO to metallic NiS. However, the recovery time is quite long (>20000 s, see Fig. 21c).

Wang et al. 198 reported a composite oxide sensor using 8% silica modified CeO₂ nanomaterials (see Fig. 21d) synthesized using a sol-hydrothermal route. The addition of silica increases the specific surface areas (83.75 m²/g) and decreases the crystal sizes. Due to the existence of silica, lots of OH⁻ species are formed on the surface of the sensor, which facilitate the adsorption of water, and the water molecules react with NH₃ to generated NH⁴⁺ and OH⁻ and decrease the electrical resistance of the sensor. As shown in Figs. 21e and 21f, the NH₃ gas sensing performance of the sensor is significantly enhanced as compared to that of pure CeO₂ at RT. Its response value reaches 3244% (defined as (ΔR/Rg) × 100%) for 80 ppm of NH₃ gas.
The composites of alkali metal oxide and SMONs have also been reported as an effective way to enhance the sensitivity for sensing acidic gases, such as NO\textsubscript{x}. As shown in the gas sensing mechanism of mesoporous K\textsubscript{2}O-In\textsubscript{2}O\textsubscript{3} nanowires in Fig. 22 the alkali metal oxides on the surfaces can serve as alkaline center, which is beneficial to the adsorption and diffusion of acidic gases. Using mesoporous Santa Barbara Amorphous Material-16 (SBA-16) as a template, Rehman et al. prepared highly crystalline mesoporous K\textsubscript{2}O-In\textsubscript{2}O\textsubscript{3} nanowires with the diameters of 4-8 nm and pore sizes of 3-5 nm. The composite nanowires possess numerous chemisorbed oxygen and alkaline centers on their surfaces. The gas sensing performance of the mesoporous K\textsubscript{2}O-In\textsubscript{2}O\textsubscript{3} composite nanowires has been significantly improved with the addition of K\textsubscript{2}O. Its response is 151.78 to 97 ppm of NO\textsubscript{x}, the response time is decreased to 12 s, and the LOD is as low as 48.5 ppb at RT.

Most reported composite SMON sensors exhibit higher response values and faster response time than those of the single phase SMONs. Many active sites can be generated in the composite SMONs, such as oxygen vacancies, heterojunctions, defects and mesopores, which can effectively enhance the sensing performance. The composite SMON can be further modified by noble metal nanoparticles, which takes advantage of the chemical sensitization and electronic sensitization of noble metal nanoparticles on the composite SMONs.

3.2.3 Gas sensors based on composites of semiconducting metal oxide nanostructures and carbon nanomaterials
Carbon nanomaterials including carbon nanotubes and graphene have been demonstrated as promising sensing materials. However, the carbon nanomaterial-based gas sensors generally show low sensitivity and slow response/recovery speeds at RT. The synergistic effect by combining SMONs and carbon nanomaterials can improve the sensing performance because: (1) conductivity is significantly improved; (2) many active sites (such as oxygen functional groups, vacancies and defects) are formed at the interfaces. Because of the fast carrier transport kinetics, the composites of the SMONs combined with carbon nanomaterials show the enhanced sensitivity and fast response/recovery at RT.

Table 6 summarizes the RT sensing properties of some composite nanostructures of the SMONs and carbon nanomaterials. Among these carbon materials, the composites of reduced graphene oxide (rGO) and SMONs are the mostly investigated one for the gas sensor applications. The rGO has been used to combine with various types of the SMONs for enhancing the gas sensing properties, and these SMONs include Fe₂O₃, In₂O₃, ZnO, Fe₃O₄, SnO₂, WO₃, NiO/SnO₂, and Pd/TiO₂.

Table 6 Room temperature sensing properties of composite nanostructures of semiconducting metal oxide nanostructures and carbon nanomaterials

<table>
<thead>
<tr>
<th>Material</th>
<th>Structure of SMONs</th>
<th>Synthesis method of SMONs</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>tₚ/rₜ</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Graphene/SnO₂</td>
<td>Nanoparticles</td>
<td>Sol-gel</td>
<td>NO₂</td>
<td>20</td>
<td>~9.5</td>
<td>&lt;1/5 min</td>
<td>5 ppm</td>
<td>124</td>
</tr>
<tr>
<td>SnO₂/rGO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>1000</td>
<td>22.87&quot;</td>
<td>100/- s</td>
<td>1 ppm</td>
<td>328</td>
</tr>
<tr>
<td>SnO₂/rGO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>1</td>
<td>3.8</td>
<td>14/190 s</td>
<td>50 ppb</td>
<td>329</td>
</tr>
<tr>
<td>WO₃/MWCNTs</td>
<td>Nanoparticles</td>
<td>Metal organic decomposition</td>
<td>NO₂</td>
<td>0.1</td>
<td>0.25&quot;</td>
<td>10.5/20 min</td>
<td>100 ppb</td>
<td>125</td>
</tr>
<tr>
<td>rGO/α-Fe₂O₃</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>5</td>
<td>3.86</td>
<td>76/946 s</td>
<td>0.1 ppm</td>
<td>126</td>
</tr>
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<td>α-Fe₂O₃/rGO</td>
<td>Nanospheres</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>90</td>
<td>150.63&quot;</td>
<td>~1648 s</td>
<td>0.18 ppm</td>
<td>331</td>
</tr>
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<td>Fe₂O₃/Graphene</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>400</td>
<td>24.2&quot;</td>
<td>275/738 s</td>
<td>~30 ppm</td>
<td>331</td>
</tr>
<tr>
<td>Graphene/ZnO</td>
<td>Spheres</td>
<td>Solvothermal</td>
<td>NO₂</td>
<td>50</td>
<td>8&quot;</td>
<td>132/164 s</td>
<td>~10 ppm</td>
<td>332</td>
</tr>
<tr>
<td>ZnO/rGO</td>
<td>Nanowalls</td>
<td>Solution</td>
<td>NO₂</td>
<td>50</td>
<td>9.61</td>
<td>25/15 s</td>
<td>~5 ppm</td>
<td>135</td>
</tr>
<tr>
<td>ZnO/rGO</td>
<td>Nanorods</td>
<td>Oriented growth</td>
<td>NO₂</td>
<td>1</td>
<td>119&quot;</td>
<td>75/132 s</td>
<td>50 ppb</td>
<td>333</td>
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<td>rGO/NiO</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>0.25</td>
<td>0.04&quot;</td>
<td>576/121 s</td>
<td>~0.25 ppm</td>
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</tr>
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<td>In₂O₃/rGO</td>
<td>Nanosheets</td>
<td>Hydrothermal</td>
<td>NO₂</td>
<td>30</td>
<td>8.25</td>
<td>4/24 min</td>
<td>~5 ppm</td>
<td>335</td>
</tr>
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<td>Layered System</td>
<td>Nanomaterial</td>
<td>Fabrication Method</td>
<td>Anion</td>
<td>ppm</td>
<td>Time</td>
<td>Temperature</td>
<td>Reaction Time</td>
<td>ppm</td>
</tr>
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<td>----------------</td>
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<td>-----</td>
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<tr>
<td>In$_2$O$_3$/rGO</td>
<td>Layers</td>
<td>Reflux</td>
<td>NO$_3$</td>
<td>97</td>
<td>1.45$^*$</td>
<td>25/-</td>
<td>s</td>
<td>970 ppb</td>
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<tr>
<td>rGO/CeO$_2$</td>
<td>Bilayer</td>
<td>Spray</td>
<td>NO$_2$</td>
<td>10</td>
<td>20.5$^8$</td>
<td>92/-</td>
<td>s</td>
<td>~1 ppm</td>
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<tr>
<td>rGO/Cu$_2$O</td>
<td>Nanoparticles</td>
<td>Chemical solution</td>
<td>NO$_2$</td>
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<td>5.2</td>
<td>29.2/76.8 s</td>
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<td>338</td>
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<td>CuO/rGO</td>
<td>Nanosheets</td>
<td>Chemical solution</td>
<td>NO$_2$</td>
<td>1</td>
<td>14</td>
<td>66/34 s</td>
<td>60 ppb</td>
<td>339</td>
</tr>
<tr>
<td>Co$_3$O$_4$/rGO</td>
<td>Thin sheets</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>800</td>
<td>~8$^8$</td>
<td>1.5/1 min</td>
<td>60 ppm</td>
<td>340</td>
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<tr>
<td>Cu$_x$O/Graphene</td>
<td>Nanoflowers</td>
<td>Reflux</td>
<td>NO$_3$</td>
<td>97</td>
<td>95.1$^8$</td>
<td>9.6/-</td>
<td>s</td>
<td>97 ppb</td>
</tr>
<tr>
<td>CeO$_2$/Graphene</td>
<td>Nanosheets</td>
<td>Solvotherrnal</td>
<td>NO$_3$</td>
<td>300</td>
<td>12.76$^8$</td>
<td>1.3/-</td>
<td>s</td>
<td>5 ppm</td>
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<tr>
<td>Graphene/SnO</td>
<td>Hybrid film</td>
<td>CVD</td>
<td>NH$_3$</td>
<td>100</td>
<td>35$^*$</td>
<td>~10/-</td>
<td>s</td>
<td>~5 ppm</td>
</tr>
<tr>
<td>SnO$_2$/rGO</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>200</td>
<td>1.3</td>
<td>8/13</td>
<td>s</td>
<td>20 ppm</td>
</tr>
<tr>
<td>SnO$_2$/MWCNTs</td>
<td>Nanocomposites</td>
<td>Microelectronic</td>
<td>NH$_3$</td>
<td>200</td>
<td>26</td>
<td>&lt;5/5 min</td>
<td>~40 ppm</td>
<td>136</td>
</tr>
<tr>
<td>rGO/TiO$_2$</td>
<td>Microspheres</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>30</td>
<td>~3.5$^8$</td>
<td>~10/10min</td>
<td>5 ppm</td>
<td>345</td>
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<tr>
<td>CuO/rGO</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>200</td>
<td>2.04</td>
<td>28/206 s</td>
<td>~100 ppm</td>
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<tr>
<td>ZnO/GrO</td>
<td>Nanosheets</td>
<td>Chemical solution</td>
<td>NH$_3$</td>
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<td>24$^8$</td>
<td>6/2-3</td>
<td>s</td>
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<tr>
<td>ZnO/CNT</td>
<td>Networks</td>
<td>Flame</td>
<td>NH$_3$</td>
<td>100</td>
<td>330</td>
<td>18.4/35 s</td>
<td>200 ppb</td>
<td>348</td>
</tr>
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<td>VO$_2$/CNT</td>
<td>Nanocomposites</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>45</td>
<td>0.04$^*$</td>
<td>290/1800 s</td>
<td>20 ppb</td>
<td>349</td>
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<tr>
<td>Graphene/SnO$_2$</td>
<td>Nanohybrids</td>
<td>Electrochemical deposition</td>
<td>HCOH</td>
<td>5</td>
<td>4.6$^a$</td>
<td>46/95 s</td>
<td>0.02 ppm</td>
<td>350</td>
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<tr>
<td>rGO/TiO$_2$</td>
<td>Nanosheets</td>
<td>Spray method</td>
<td>HCOH</td>
<td>0.5</td>
<td>0.4$^a$</td>
<td>70/126 s</td>
<td>~0.1 ppm</td>
<td>351</td>
</tr>
<tr>
<td>SnO$_2$/rGO</td>
<td>Quantum wires</td>
<td>Spin coating</td>
<td>H$_2$S</td>
<td>50</td>
<td>33</td>
<td>2/292 s</td>
<td>43 ppb</td>
<td>4</td>
</tr>
<tr>
<td>TiO$_2$/rGO</td>
<td>Nanotubes</td>
<td>Hydrothermal</td>
<td>Methanol</td>
<td>800</td>
<td>96.93$^8$</td>
<td>18/61 s</td>
<td>10 ppm</td>
<td>352</td>
</tr>
<tr>
<td>ZnO/MWNTs</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>Ethanol</td>
<td>50</td>
<td>4.5$^g$</td>
<td>7/11 s</td>
<td>~5 ppm</td>
<td>353</td>
</tr>
<tr>
<td>CuO/rGO</td>
<td>Nanocomposites</td>
<td>Hydrothermal</td>
<td>CO</td>
<td>1</td>
<td>2.56$^a$</td>
<td>70/160 s</td>
<td>0.25 ppm</td>
<td>354</td>
</tr>
<tr>
<td>SnO$_2$/MWCNT</td>
<td>Nanofibers</td>
<td>Electrospinning</td>
<td>CO</td>
<td>50</td>
<td>1.29</td>
<td>-</td>
<td>47 ppm</td>
<td>355</td>
</tr>
<tr>
<td>SnO$_2$/rGO</td>
<td>Hybrid film</td>
<td>Hydrothermal</td>
<td>Acetone</td>
<td>10</td>
<td>2.1$^g$</td>
<td>107/95 s</td>
<td>~10 ppm</td>
<td>356</td>
</tr>
<tr>
<td>ZnO/Graphene</td>
<td>Nanotubes</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>100</td>
<td>28.08$^8$</td>
<td>30/-150 s</td>
<td>10 ppm</td>
<td>357</td>
</tr>
<tr>
<td>CuO/rGO/CuO</td>
<td>Sandwich</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>1500</td>
<td>~12$^9$</td>
<td>80/60 s</td>
<td>10 ppm</td>
<td>358</td>
</tr>
<tr>
<td>F-MWCNTs/SnO$_2$</td>
<td>Networks</td>
<td>Sputtering</td>
<td>H$_2$</td>
<td>500</td>
<td>5.4$^a$</td>
<td>~9 s</td>
<td>-</td>
<td>359</td>
</tr>
<tr>
<td>SnO$_2$/Ni-graphene</td>
<td>Nanoparticles</td>
<td>Chemical solution</td>
<td>N$\text{O}$</td>
<td>40</td>
<td>15</td>
<td>-</td>
<td>-</td>
<td>360</td>
</tr>
<tr>
<td>Pd/SnO$_2$/rGO</td>
<td>Nanoparticles</td>
<td>Chemical solution</td>
<td>H$_2$</td>
<td>10000</td>
<td>50$^a$</td>
<td>-</td>
<td>100 ppm</td>
<td>361</td>
</tr>
<tr>
<td>Pd/SnO$_2$/rGO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>CO</td>
<td>1600ppm</td>
<td>9.5$^a$</td>
<td>2 min/2 min</td>
<td>~50ppm</td>
<td>362</td>
</tr>
<tr>
<td>Pd/SnO$_2$/rGO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>Methane</td>
<td>4000ppm</td>
<td>2.07$^a$</td>
<td>10 min/2</td>
<td>-</td>
<td>363</td>
</tr>
<tr>
<td>Ag/SnO$_2$/rGO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>5</td>
<td>2.17</td>
<td>49/339 s</td>
<td>1 ppm</td>
<td>364</td>
</tr>
<tr>
<td>Pd/SnO$_2$/rGO</td>
<td>Nanoparticles</td>
<td>Chemical solution</td>
<td>NH$_3$</td>
<td>5 ppm</td>
<td>7.6$^a$</td>
<td>7min/50min</td>
<td>~5ppm</td>
<td>365</td>
</tr>
<tr>
<td>Material</td>
<td>Shape</td>
<td>Preparation Method</td>
<td>Gas</td>
<td>Concentration</td>
<td>Time</td>
<td>LOD</td>
<td></td>
<td></td>
</tr>
<tr>
<td>--------------------------</td>
<td>-----------------</td>
<td>-----------------------------</td>
<td>--------------</td>
<td>---------------</td>
<td>------------</td>
<td>------------</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Pd/TiO₂/rGO</td>
<td>Nanorods</td>
<td>One-pot polyol</td>
<td>NH₃</td>
<td>50</td>
<td>14.9⁰</td>
<td>2.4 ppm</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Pd/RGO/TiO₂</td>
<td>Nanotube</td>
<td>Electrochemical anodization</td>
<td>Methanol</td>
<td>700</td>
<td>~70⁰</td>
<td>-</td>
<td></td>
<td></td>
</tr>
<tr>
<td>CNT/Au/SnO₂</td>
<td>Nanotube</td>
<td>Chemical solution</td>
<td>CO</td>
<td>2500</td>
<td>70</td>
<td>-</td>
<td></td>
<td></td>
</tr>
<tr>
<td>WO₃/S/rGO</td>
<td>Hydrothermal</td>
<td></td>
<td>NO₂</td>
<td>20 ppm</td>
<td>149.5⁰</td>
<td>0.25 ppm</td>
<td></td>
<td></td>
</tr>
<tr>
<td>SnO₂/S/rGO</td>
<td>Hydrothermal</td>
<td></td>
<td>NO₂</td>
<td>5 ppm</td>
<td>20.31⁰</td>
<td>1ppm</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Notes:
- C = concentration;
- \( t_{\text{res}}/t_{\text{rec}} \) = response time/recovery time;
- LOD = limit of detection;
- Response is defined as \( R_a/R_g \) (for reducing gases) or \( R_g/R_a \) (for oxidizing gases), \( R_a \): resistance of the sensor exposed to reference, \( R_g \): resistance of the sensor exposed to target.
- * Here the response is defined as \( \Delta R/R_g \) (for reducing gases) or \( \Delta R/R_a \) (for oxidizing gases), \( \Delta R \): the change in resistance.
- # Here the response is defined as \( (\Delta R/R_g) \times 100\% \) (for reducing gases) or \( (\Delta R/R_a) \times 100\% \) (for oxidizing gases).

Fig. 23 (a) TEM image of the α-Fe₂O₃/rGO composite; (b) response values of the sensor based on α-Fe₂O₃/rGO at different NO₂ concentrations; (c) response histogram of the sensor to different gases. ³³⁰, © 2014 The Royal Society of Chemistry. (d) Band gap diagrams of SnO₂-nanorods/reduced graphene oxide nanostructures before and after combination. ³⁴⁴, © 2017 Elsevier. (e) TEM image of the ZnO/rGO composite; (f) response/recovery curves to 50 ppm NO₂ of the sensor based on a-ZnO/rGO or ZnO. ³¹⁵, © 2017 Elsevier.
The RT NO$_2$ sensor fabricated using rGO/$\alpha$-Fe$_2$O$_3$ exhibits a response value of 3.86 to 5 ppm NO$_2$, which is better than that of pure rGO, whose response is 1.38. In addition, it has significantly shorter response/recovery times of 32/1432 s, compared with those of the sensors made of the pure rGO (2059s, 40130s). Dong et al. reported a nanocomposite combining $\alpha$-Fe$_2$O$_3$ nanosphere and reduced graphene oxide nanosheets as shown in Fig. 23a. The $\alpha$-Fe$_2$O$_3$ nanospheres with a diameter from 40 to 50 nm were grown on the surface of graphene nanosheets using a hydrothermal method, and the improved sensing performance from the sensor made of this composite was attributed to the synergistic effect of $\alpha$-Fe$_2$O$_3$/rGO and large specific surface areas. In addition to the interaction of NO$_2$ with O$_2^-$ on the surface of $\alpha$-Fe$_2$O$_3$, NO$_2$ molecules also capture the electrons from the rGO to form NO$_2^-$, thus resulting in an increased hole density, and a decreased resistance of rGO. Therefore, the $\alpha$-Fe$_2$O$_3$/rGO nanocomposites exhibit a much higher response to NO$_2$ at RT than that of either the pure rGO or $\alpha$-Fe$_2$O$_3$ nanospheres. Its LOD for the NO$_2$ gas is as low as 0.18 ppm (see Fig. 23b), and a good selectivity has been demonstrated against CO, HCHO, H$_2$S, NH$_3$ and C$_2$H$_5$OH (see Fig. 23c).

Besides the good conductivity of carbon materials, the improved interfacial electron transfer is another a key factor for improving the SMONs’ sensing performance by adding carbon nanomaterials. For example, an RT NH$_3$ gas sensor was fabricated using SnO$_2$ nanorods/rGO composite nanostructures, and the sensor shows fast response/recovery with times of 8/13 s to 200 ppm NH$_3$ at RT. Fig. 23d shows the band gap diagrams of SnO$_2$-nanorods/rGO nanostructures before and after the combination of two nanostructures. The p-n heterojunctions are formed at the interface between the rGO and SnO$_2$ as the rGO is a p-type semiconductor. The Fermi energy of the rGO is higher than that of the SnO$_2$, so electrons can be transported to SnO$_2$ from the rGO, which can further enhance the adsorption of NH$_3$ molecules to improve the gas sensing performance.

Formation of heterojunction structures was found to contribute the sensing performance of the ZnO nanowall/rGO nanocomposite, in which the ZnO nanowalls
were vertically grown on the rGO thin film using a soft solution process to obtain a heterojunction structure as shown in Fig. 23e. At the interfaces between the rGO and ZnO nanowalls of the p-n heterostructures, the Fermi energy of the rGO is higher than that of the ZnO. Therefore, the charge transfer from rGO layers to the conduction band of ZnO enhances the adsorption of NO$_2$ molecules. If compared with the sensor made of pure ZnO nanowalls, the sensor made of the ZnO/rGO heterojunction shows a higher response and shorter response/recovery times to NO$_2$ at RT (see Fig. 23f)\textsuperscript{135}.

Another key mechanism for the improved gas sensing performance for the SMONs/rGO composite is the increased oxygen vacancy on the SMONs, such as in the SnO$_2$-rGO composite\textsuperscript{329}. Due to the p-n heterojunction formed at the interfaces between n-type SnO$_2$ and p-type rGO, electrons can easily transfer from the SnO$_2$ into the rGO to form abundant oxygen vacancies on the surface of SnO$_2$. These oxygen vacancies are the electronic charge carriers to increase the conductivity of the composite, and they can adsorb oxygen molecules to form more active sites, which will capture electrons from SnO$_2$ and form the oxygen ions to react with target gas molecules. The oxygen vacancy also facilitates the fast adsorption of the NO$_2$ molecules onto the surface of SnO$_2$. All these reasons are contribute to the excellent sensing properties of SnO$_2$/rGO composite based sensors to NO$_2$ gas at RT.

However, the recovery of these composites of SMONs with carbon materials is very slow, although UV-light illumination can be used to enhance a fast and complete recovery. For example, rGO-CeO$_2$ hybrids were synthesized by anchoring small CeO$_2$ nanocrystals onto rGO nanosheets using a solvothermal method, and the RT NO$_2$ gas sensor made of this hybrid showed a full recovery time of several hours\textsuperscript{371}. However, the recovery time can be significantly reduced to within 258 s with the aid of UV-light illumination. This UV light enhancement will be further discussed in Section 3.3.
Fig. 24. (a) TEM image of the SnO$_2$ quantum wires/rGO nanosheets, the inset shows the response/recovery of the sensor based on SnO$_2$ quantum wires/rGO nanosheets for different H$_2$S concentrations; (b) response histogram of the SnO$_2$ quantum wires/rGO nanosheets based sensor to different gases. © 2016 American Chemical Society. (c) Response values at different concentrations of NH$_3$ gas for 2%CNTs/ ZnO networks (the inset presents the sensor structure); (d) long-time stability of the RT gas sensors to 100 ppm of NH$_3$ at 30% RH. © 2017 American Chemical Society.

Fig. 24a shows that an ultra-fast response time for sensing of H$_2$S gas (which is the fastest reported in literature with a value of 2s to 50 ppm of H$_2$S) can be achieved using a sensor made of SnO$_2$ quantum wires/rGO nanosheets. The electronic interactions of SnO$_2$ quantum wires and rGO nanosheets can enhance the electron transport, and increase the response and recovery speed. In addition, the sensor made of the SnO$_2$ quantum wires/rGO nanosheets shows a response of 33 with an excellent selectivity against other types of gases including NH$_3$, SO$_2$, NO$_2$ and ethanol at RT as shown in Fig. 24b. In this composite material, the ultrathin and one-dimensional microstructure of SnO$_2$ quantum wires is effective in providing large surface areas for gas adsorption and reaction.
The sensors made of composites integrating the rGO with p-type SMONs (such as CuO and Co₃O₄) also show enhanced sensing performance. The RT gas sensor based on the CuO/rGO nanohybrids can detect a low-concentration of NO₂ with a highly sensitive response (14 to 1 ppm NO₂) and fast response/recovery times (66/34 s), mainly due to formation of large surface areas and enhanced carrier transfers between the CuO and NO₂ molecules. Furthermore, Ding et al. reported that the integration of chemically functionalized three-dimension graphene oxide hydro-gels with metal-organic frameworks derived Co₃O₄ nanostructures achieved ultra-high response, short response time and distinct cross-selectivity.

The composite of SMONs with carbon nanotubes (CNT) such as SWCNTs/SnO₂ and CNT/SnO₂ can also improve the sensing performance. The p-n junctions formed between the SMONs and p-type MWCNTs are responsible for their enhanced gas sensing responses. For example, Srivastava et al. reported an RT NO₂ gas sensor based on multi-walled carbon nanotubes/SnO₂. The sensor exhibits a much higher response to NO₂ than the pure SnO₂ based sensor operated at RT. Due to the good conductivity of the CNTs and the high porosity of the ZnO networks, the response value of 2%CNTs/ZnO networks has been increased from 37 to 330 when the sensor was exposed to 100 ppm NH₃ at RT (see Fig. 24c). The response/recovery times are decreased from 58/61 s to 18/35 s, respectively. The sensor also displays a good stability over a duration of one month (see Fig. 24d). In addition, the CNTs can serve as acceptors for the released electrons, which are injected into the SMONs from the target gases. A H₂S gas sensor made of nanocomposite of SnO₂ quantum dot/MWCNT based H₂S gas sensor reported by Liu et al. exhibited a high response value of 108 to 50 ppm H₂S with fast response/recovery times of 23/44 s.

Adding the metal noble nanoparticles into the composite is another method to further improve the gas sensing performance of SMONs/rGO composite. Being good catalysts, these noble metal nanoparticles can enhance the catalytic efficiency by creating extra new sites to promote fast adsorption of gas molecules and decrease the reaction temperatures by lowering the activation energy of the gas sensing reactions. For example, Shojae et al. reported that the nanocomposites of Pd loaded SnO₂ and
partially reduced graphene oxide showed a good performance to detect CO from 50 to 1600 ppm with fast response and recovery times at 26 °C. The Pd/SnO₂/rGO based H₂ sensor 361 and Pd/TiO₂/rGO based NH₃ sensor 366 prepared using a chemical solution method exhibited higher sensitivity and faster response time than those of the SnO₂/rGO and TiO₂/rGO sensors. In addition of Pd nanoparticles, Ag nanoparticles were also be used to improve the RT sensing performance of SnO₂-rGO hybrids for detection of NO₂. The Ag/SnO₂/rGO hybrid composites exhibits much shorter response time and recovery time (49 s and 339 s) to 5 ppm NO₂ at RT than those of the SnO₂-rGO hybrids (415 s and 740 s) 364.

Similar to those cases for the rGO/SMONs composites, modifications of the CNT/SMONs composites using noble metal nanoparticles can also improve their gas sensing property. For example, CNT/Au/SnO₂ composites were synthesized by homogeneously coating SnO₂ and Au nanocrystals onto the CNTs, and then applied to detect CO gas at RT 368. The sensor made of the CNT/Au/SnO₂ composites shows a better selectivity to the CO than that of the CNT/SnO₂ composite. It has a high sensitivity of 70 when exposed to 2500 ppm of CO, and shows a higher sensitivity values to CO gases with different concentrations varied from 500 to 2500 ppm when compared with those of the Au/SnO₂ composites.

In brief, due to the high conductivity of carbon nanomaterials and the formation of heterojunction, the response/recovery times of the composites of SMONs with carbon nanomaterials are much shorter than those from the pure SMONs, although it seems that the increase of response values achieved using these composites might be less significant.

3.3 Room temperature photoactivated gas sensors based on semiconducting metal oxide nanostructures

Generally, many of the SMONs-based gas sensors are needed to heat up for the best gas sensing performance, which is inconvenient in many situations. Instead, UV light can be used to activate and enhance the gas sensing performance of SMONs operated at RT 380. The reported SMONs whose sensing properties can be improved by UV light are mainly ZnO 381-385, In₂O₃ 386 387, TiO₂ 388 389 and SnO₂ 390, 391, which have been
summarized in Table 7. The SMONs can absorb the UV light to produce photo-generated electrons and holes. The photo-generated electrons on the surface can enhance the chemisorption of oxygen molecules to form more $O_2^-$ as listed in the Eq. (20) and (21)\textsuperscript{392}, thus can enhance the sensitivity and response/recovery times of the SMONs under the UV light.

$$h\nu \rightarrow h^+ + e^- \quad (20)$$

$$O_2 + e^- \rightarrow O_2^- \quad (21)$$

Table 7 Room temperature sensing properties of semiconducting metal oxide nanostructures enhanced by UV light

<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>$t_{res}/t_{rec}$</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>ZnO</td>
<td>Microwires</td>
<td>Surface etching</td>
<td>NO$_2$</td>
<td>20</td>
<td>411$^a$</td>
<td>221/118 s</td>
<td>~10 ppm</td>
<td>381</td>
</tr>
<tr>
<td>ZnO</td>
<td>Nanowires</td>
<td>Wet-chemical</td>
<td>C$_2$H$_5$OH</td>
<td>700</td>
<td>85$^a$</td>
<td>-</td>
<td>~100 ppm</td>
<td>382</td>
</tr>
<tr>
<td>ZnO</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>HCHO</td>
<td>110</td>
<td>11.5$^a$</td>
<td>14/0.5 min</td>
<td>1.8 ppm</td>
<td>383</td>
</tr>
<tr>
<td>ZnO</td>
<td>Nanofibers</td>
<td>Electrospinning</td>
<td>HCHO</td>
<td>100</td>
<td>12.3</td>
<td>32/17 s</td>
<td>~5 ppm</td>
<td>384</td>
</tr>
<tr>
<td>In$_2$O$_3$</td>
<td>Nanostructures</td>
<td>Arc-discharge</td>
<td>NO</td>
<td>50</td>
<td>41.7</td>
<td>~10/- min</td>
<td>~2 ppm</td>
<td>386</td>
</tr>
<tr>
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<td>Nanoporous particles</td>
<td>Nanocasting</td>
<td>Ozone</td>
<td>0.22</td>
<td>200</td>
<td>2.5/- min</td>
<td>50 ppb</td>
<td>387</td>
</tr>
<tr>
<td>TiO$_2$</td>
<td>Hollow microspheres</td>
<td>Hydrothermal</td>
<td>HCHO</td>
<td>5</td>
<td>~40</td>
<td>40/55 s</td>
<td>124 ppb</td>
<td>388</td>
</tr>
<tr>
<td>TiO$_2$</td>
<td>Thin film</td>
<td>Rf-sputter</td>
<td>NO$_2$</td>
<td>250</td>
<td>~1.8$^a$</td>
<td>100/210 s</td>
<td>100 ppm</td>
<td>389</td>
</tr>
<tr>
<td>SnO$_2$</td>
<td>Nanowires</td>
<td>-</td>
<td>NO$_2$</td>
<td>10</td>
<td>~85$^a$</td>
<td>10/15 min</td>
<td>~0.1 ppm</td>
<td>390</td>
</tr>
<tr>
<td>ZnO/SnO$_2$</td>
<td>Nanorods</td>
<td>Wet chemical</td>
<td>NO$_2$</td>
<td>0.5</td>
<td>1266$^*$</td>
<td>7/8 min</td>
<td>~200 ppb</td>
<td>393</td>
</tr>
<tr>
<td>SnO$_2$/TiO$_2$</td>
<td>Hollow spheres</td>
<td>Thermal evaporation</td>
<td>Ethanol</td>
<td>100</td>
<td>160</td>
<td>50/150 s</td>
<td>-</td>
<td>394</td>
</tr>
<tr>
<td>NiO/TiO$_2$</td>
<td>Microspheres</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>100</td>
<td>140$^a$</td>
<td>~400/~40 s</td>
<td>~10 ppm</td>
<td>395</td>
</tr>
<tr>
<td>Ag/ZnO</td>
<td>Nanorods</td>
<td>Hydrothermal</td>
<td>HCHO</td>
<td>40</td>
<td>119.8$^a$</td>
<td>-</td>
<td>5 ppm</td>
<td>396</td>
</tr>
<tr>
<td>ZnO</td>
<td>Nanoparticles</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>20</td>
<td>85$^*$$^a$</td>
<td>26/16 s</td>
<td>~1 ppm</td>
<td>397</td>
</tr>
</tbody>
</table>

Notes:

$C = \text{concentration}$;

$t_{res}/t_{rec} = \text{response time/recovery time}$;

$LOD = \text{limit of detection}$;

Response is defined as $R_a/R_g$ (for reducing gases) or $R_g/R_a$ (for oxidizing gases), $R_a$:
resistance of the sensor exposed to reference, $R_g$: resistance of the sensor exposed to target:
* Here the response is defined as $\Delta R/R_g$ (for reducing gases) or $\Delta R/R_a$ (for oxidizing gases), $\Delta R$: the change in resistance.
# Here the response is defined as $(\Delta R/R_g) \times 100\%$ (for reducing gases) or $(\Delta R/R_a) \times 100\%$ (for oxidizing gases).

With the assistance of the UV LED (photon energy of 2.5 mW), the RT gas sensor made of mesoporous hollow TiO$_2$ microspheres exhibited a high response to formaldehyde with faster response/recovery (40/50 s) and good selectivity. Higher response has also been reported using the sensor made of ZnO/SnO$_2$ composite materials to detect NO$_2$ under the UV light illumination at RT. After the sensing materials is exposed to NO$_2$ gas, the NO$_2$ molecules will collect the photo-generated electrons to form the NO and O$_2^-$ as shown in Eq. (22), which results in an increase in the resistance of the sensor.

$$2\text{NO}_2(g) + e^-(\text{hv}) \rightarrow 2\text{NO}(\text{hv}) + \text{O}_2^-(\text{hv})$$ (22)

Simultaneously, a heterojunction is formed at the interfaces between ZnO and SnO$_2$. The photogenerated electrons are transferred from the ZnO to SnO$_2$ due to the higher Fermi energy level of ZnO than that of SnO$_2$ (see Fig. 25a). The efficient charge separation increases charge concentrations on the surface of SnO$_2$, which remarkably improves the sensitivity under the UV light stimulation at RT as shown in Figs. 25b.

![Fig. 25.](image)

Fig. 25. (a) Schematic diagram of the carrier transport under UV light and the electron-hole pair separation on heterostructure of ZnO/SnO$_2$ composite; (b) Response/recovery of ZnO/SnO$_2$ composite at different concentration of NO$_2$ with and without UV light stimulation at room temperature. © 2011 Elsevier.
Apart from the UV light, visible light (including blue light and white light) assisted RT gas sensors with enhanced performance have also been reported. Klaus et al. reported a blue light (460 nm) activated ozone gas sensor based on nanoporous In$_2$O$_3$ particles, which showed a high response value of 200 and a low LOD of 50 ppb at RT. Geng et al. reported that a sensor made of Cu$_x$O$_{1-y}$/ZnO$_{1-a}$ nanocomposites showed enhanced NO$_2$ sensing properties at RT with high response and good selectivity after illuminated with the white light. Similarly, infrared (IR) should also be beneficial for the improvement in the sensing performance.

Although the photoactivated SMONs gas sensors could achieve the improved gas sensing performance operated at RT, the light-emitting diodes, UV source, or infrared light, as well as optical power detection device are necessary to be used, which will increase the size and production cost of the sensor device. The integration and shrinkage of the devices along with mass production capabilities are challenges. In addition, for the application of the gas sensors in the real environment, the gas sensor will be exposed in the air for real-time monitoring. The sunlight will severely influence the gas sensing response.

4. Mechanically flexible gas sensors based on semiconducting metal oxide nanostructures

Mechanically flexible gas sensors are in a great demand due to their promising applications in wearable electronic devices. The SMONs with a potentially higher carrier mobility and mechanical robustness are good candidates to the realization of stretchable and flexible sensors. The mechanically flexible and wearable RT gas sensors based on the SMONs have been an active research area recently as listed in Table 8. Compared with those on the rigid substrates, the wearable devices need substrates which are flexible, light weight, transparent, transportable, with a small volume, and low cost. Due to their excellent dielectric properties, and thermal and chemical stability, many plastic substrates have been used as flexible substrates for the RT gas sensors including polyethylene terephthalate (PET), polypropylene (PP), polyimide (PI), Polyvinyl Acetate (PVA), and nylon.
<table>
<thead>
<tr>
<th>Material</th>
<th>Structure</th>
<th>Substrate</th>
<th>Synthesis method</th>
<th>Target gas</th>
<th>C (ppm)</th>
<th>Response</th>
<th>$t_{res}/t_{rec}$</th>
<th>LOD</th>
<th>Ref</th>
</tr>
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<tbody>
<tr>
<td>CuO</td>
<td>Nanorectangles</td>
<td>PET</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>5</td>
<td>$&lt;0.25^*$</td>
<td>90/120 s</td>
<td>5 ppm</td>
<td>223</td>
</tr>
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<td>ZnO</td>
<td>Nanorods</td>
<td>Nylon</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>500</td>
<td>$10^g$</td>
<td>149/122 s</td>
<td>-</td>
<td>409</td>
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<tr>
<td>ZnO</td>
<td>Nanowire</td>
<td>PET</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>1000</td>
<td>5$^g$</td>
<td>$~600/-$ s</td>
<td>-</td>
<td>402</td>
</tr>
<tr>
<td>Ag/ZnO</td>
<td>Nanorods</td>
<td>PI</td>
<td>Hydrothermal</td>
<td>C$_2$H$_2$</td>
<td>1000</td>
<td>26.2</td>
<td>66/68 s</td>
<td>3 ppm</td>
<td>410</td>
</tr>
<tr>
<td>Ga/ZnO</td>
<td>Nanorods</td>
<td>PI/PET</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>1000</td>
<td>91$^{1g}$</td>
<td>$~18.8/-$ s</td>
<td>0.2 ppm</td>
<td>265</td>
</tr>
<tr>
<td>Pd/ZnO</td>
<td>Nanorods</td>
<td>PI/PET</td>
<td>Hydrothermal</td>
<td>H$_2$</td>
<td>1000</td>
<td>91.2$^{1g}$</td>
<td>$~18.8/-$ s</td>
<td>0.2 ppm</td>
<td>173</td>
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<td>ZnO$_{1-x}$</td>
<td>Sheet-like</td>
<td>PP</td>
<td>Suspension flame spraying</td>
<td>NO$_2$</td>
<td>1</td>
<td>2.568$^*$</td>
<td>60/230 min</td>
<td>0.25 ppm</td>
<td>405</td>
</tr>
<tr>
<td>ZnO</td>
<td>Nanoparticles</td>
<td>Cotton fabrics</td>
<td>Sol-gel</td>
<td>NH$_3$</td>
<td>100</td>
<td>9</td>
<td>39/34 s</td>
<td>-</td>
<td>411</td>
</tr>
<tr>
<td>In/Ga/Zn/Oxide</td>
<td>Thin-Film</td>
<td>PI</td>
<td>CVD</td>
<td>NO$_2$</td>
<td>5</td>
<td>$~1.3$</td>
<td>-</td>
<td>2 ppm</td>
<td>407</td>
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<tr>
<td>PdO/Co$_3$O$_4$</td>
<td>Nanocube</td>
<td>PI</td>
<td>Chemical precipitation</td>
<td>NO$_2$</td>
<td>20</td>
<td>27.33$^g$</td>
<td>-</td>
<td>1 ppm</td>
<td>408</td>
</tr>
<tr>
<td>SnO$_2$/SnS$_2$</td>
<td>Nanotube</td>
<td>PET</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>100</td>
<td>2.48</td>
<td>21/110 s</td>
<td>1 ppm</td>
<td>403</td>
</tr>
<tr>
<td>CeO$_2$/CuBr</td>
<td>Nanoparticles</td>
<td>PI</td>
<td>Electronbeam evaporation</td>
<td>NH$_3$</td>
<td>5</td>
<td>68</td>
<td>112/74 s</td>
<td>20 ppb</td>
<td>412</td>
</tr>
<tr>
<td>Polyaniline/CeO$_2$</td>
<td>Thin film</td>
<td>PI</td>
<td>Self-assembly</td>
<td>NH$_3$</td>
<td>50</td>
<td>262.7$^g$</td>
<td>14/6 min</td>
<td>16 ppb</td>
<td>413</td>
</tr>
<tr>
<td>WO$_3$-g</td>
<td>Film</td>
<td>PI</td>
<td>Granule spray</td>
<td>NO$_2$</td>
<td>10</td>
<td>18500$^g$</td>
<td>17/25 s</td>
<td>1.88 ppm</td>
<td>414</td>
</tr>
<tr>
<td>Polyaniline/WO$_3$</td>
<td>Flowerlike</td>
<td>PET</td>
<td>Polymerization</td>
<td>NH$_3$</td>
<td>10</td>
<td>7</td>
<td>13/49 s</td>
<td>500 ppb</td>
<td>415</td>
</tr>
<tr>
<td>rGO/WO$_3$</td>
<td>Nanoneedle</td>
<td>PET</td>
<td>Hydrothermal</td>
<td>Isopropanol</td>
<td>200</td>
<td>$~8.5$</td>
<td>60/- s</td>
<td>1 ppm</td>
<td>404</td>
</tr>
<tr>
<td>MWCNTs/WO$_3$</td>
<td>Nanoparticle</td>
<td>PET</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>5</td>
<td>14$^g$</td>
<td>10/27 min</td>
<td>0.1 ppm</td>
<td>416</td>
</tr>
<tr>
<td>WO$_3$/MWCNT/rGO</td>
<td>Nanoparticle</td>
<td>PI/PET</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>5</td>
<td>17$^g$</td>
<td>7/15 min</td>
<td>1 ppm</td>
<td>417</td>
</tr>
<tr>
<td>SWNT/Fe$_3$O$_5$</td>
<td>Composite</td>
<td>PP</td>
<td>CVD</td>
<td>NO$_2$</td>
<td>100</td>
<td>18.3$^g$</td>
<td>-</td>
<td>$~1$ ppm</td>
<td>406</td>
</tr>
<tr>
<td>Polyaniline/a-Fe$_3$O$_5$</td>
<td>Fiber network</td>
<td>PET</td>
<td>Sol-gel</td>
<td>NH$_3$</td>
<td>100</td>
<td>72$^g$</td>
<td>50/1575 s</td>
<td>2.5 ppm</td>
<td>418</td>
</tr>
<tr>
<td>Cellulose/Fe$_3$O$_5$</td>
<td>Nanoparticle</td>
<td>PET</td>
<td>Hydrothermal</td>
<td>NO$_2$</td>
<td>200</td>
<td>$~1100^g$</td>
<td>50/30 s</td>
<td>1 ppm</td>
<td>419</td>
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<tr>
<td>In$_2$O$_3$</td>
<td>Cubic crystals</td>
<td>PVA</td>
<td>Hydrothermal</td>
<td>Ethanol</td>
<td>100</td>
<td>$~1.4$</td>
<td>5/3 s</td>
<td>10 ppm</td>
<td>105</td>
</tr>
<tr>
<td>Au/In$_2$O$_3$/Polyaniline</td>
<td>Nanospheres</td>
<td>PI</td>
<td>Hydrothermal</td>
<td>NH$_3$</td>
<td>100</td>
<td>46</td>
<td>118/144 s</td>
<td>-</td>
<td>420</td>
</tr>
</tbody>
</table>

**Notes:**
\[ C = \text{concentration}; \]
\[ t_{\text{res}}/t_{\text{rec}} = \text{response time/recovery time}; \]
\[ \text{LOD} = \text{limit of detection}; \]

Response is defined as \( R_a/R_g \) (for reducing gases) or \( R_g/R_a \) (for oxidizing gases), \( R_a \): resistance of the sensor exposed to reference, \( R_g \): resistance of the sensor exposed to target:

* Here the response is defined as \( \Delta R/R_g \) (for reducing gases) or \( \Delta R/R_a \) (for oxidizing gases), \( \Delta R \): the change in resistance.
# Here the response is defined as \( (\Delta R/R_g) \times 100\% \) (for reducing gases) or \( (\Delta R/R_a) \times 100\% \) (for oxidizing gases).

For many of these flexible RT gas sensors, a sensitive layer such as ZnO nanorods is often used to deposit onto the device, for example, ZnO nanorods/nylon \(^{409}\), Ga-ZnO nanorods/PI \(^{265}\), Pd-ZnO nanorods/PI/PET \(^{173}\). The aqueous solution method to prepare these ZnO nanorod layers on the polymer substrate is facile with advantages of low growth temperature and easy modifications. For example, Mohammad et al. \(^{409}\) prepared well-aligned ZnO nanorods on a thin nylon substrate with a thickness of 15 \( \mu \text{m} \) using a hydrothermal process, and then made \( \text{H}_2 \) gas sensor. There are many contact points among ZnO nanorods which form paths of electric carriers and result in the improvement of electron transport. The mechanically flexible hydrogen gas sensor exhibited a good response value of 109\% (defined as \( (\Delta R/R_g) \times 100\% \)) with fast response/recovery.

![Fig. 26. (a) SEM images of Pd/ZnO nanorods after 10\(^3\) times bending/relaxing. (b) response/recovery curves of the flexible sensor to \( \text{H}_2 \) at different bending angles (c) the reliability test of the flexible sensor. \(^{173}\), © 2013 Elsevier.](image)

Rashid et al. \(^{173}\) prepared vertically aligned ZnO nanorods on the PI substrate using a hydrothermal method, and then made the sensors for hydrogen detection at RT. Pd nanoparticles with 10 nm in size were further sputtered on the surface of ZnO nanorods.
using an RF magnetron sputtering. After bent for $10^3$ cycles, there were no cracks or breaks on the ZnO nanorod film (see Fig. 26a). Such the flexible hydrogen sensors had a response value $\sim 91\%$ (defined as $(\Delta R/R_g) \times 100\%$) for 1000 ppm hydrogen with good repeatability and stability, and a low LOD of 0.2 ppm at RT. The gas sensing performance at different bent angles from $0^\circ$ to $90^\circ$ did not exhibit apparent changes (see Fig. 26b). Even after the sensor was bent to the curvature angle of $90^\circ$ for $10^5$ cycles, the sensing performance of this flexible H$_2$ sensor did not show any degradation (see Fig. 26c). The vertically well-aligned ZnO nanorods with the Pd catalyst on Ga-modified ZnO seed layer on flexible PI substrate also showed good H$_2$ sensing properties and good mechanical flexibility at RT with good repeatability, stability and low LOD of 0.2 ppm, even after bent at a curvature angle of $90^\circ$.

In addition to being directly grown onto the plastic substrates, the ZnO nanowires were also transferred onto plastic substrates of PET to fabricate a flexible gas sensor using various methods, including slide transfer, roll transfer and heat transfer. 2D sheet-like ZnO layer was deposited onto the flexible polypropylene papers using a suspension flame spraying method, and the prepared ZnO flexible sensor exhibited good responses and stability to sub-ppm level of NO$_2$ at RT under white LED light illumination.

The other types of SMONs have also been applied for making the flexible RT gas sensors, and these include WO$_3$, SnO$_2$, CeO$_2$, Co$_3$O$_4$, In$_2$O$_3$, etc. For example, Ryu *et al.* fabricated flexible RT NO$_2$ gas sensors based on a WO$_3-\delta$ film on a plastic substrate of polyimide (PI) using granule spray method with a vacuum process. The sensor has a response up to 18500% to 10 ppm NO$_2$ with fast response/recovery times of 17/25 s and reliable flexibility after 4000 bending/extending cycles. For another example, a nanocomposite of polyaniline and nonflower-like WO$_3$ synthesized using a facile chemical oxidation polymerization process was prepared on the PET substrate to fabricate a NH$_3$ flexible sensors, which shows high response and fast response/recovery times (13/49 s) to 10 ppm NH$_3$ operated at RT.

Modifying the SMONs using the polyaniline (PANI) can effectively enhance the sensing performance and stable of the flexible gas sensors, such as PANI-CeO$_2$, etc.
PANI/α-Fe₂O₃ and PANI/WO₃. The morphology and sensing performance of flexible RT NH₃ gas sensors based on PANI-CeO₂ nanocomposite thin film are stable after bent/cycled for 500 times ⁴¹₃. Furthermore, adding the noble metals into the SMONS/PANI composites can further improve its RT sensing performance. For examples, after adding the Au nanoparticles, the response of the RT NH₃ gas sensor made of the composite of mesoporous In₂O₃ nanospheres/polyaniline has been increased up to 4 times higher ⁴²⁰.

**Fig. 27.** (a) SEM images of 5%rGO/WO₃·0.33H₂O deposited on polyethylene terephthalate, the inset is the photograph of the flexible gas sensor, (b) response/recovery curves to isopropanol with different concentration. ⁴⁰⁴, © 2018 Royal Society of Chemistry. (c) Responses of the SWNT/Fe₂O₃ gas sensor to 20 ppm H₂S under different bending angles from 0° to 180° and returned to 0°. ⁴⁰⁶, © 2017 Elsevier. (d) SEM images of the MWCNTs/WO₃ composite, (e) response curves to 5 ppm NO₂ at RT under different bending angles, (f) responses to different NO₂ concentration at RT after bending/relaxing several times (90° angle). ⁴¹₆, © 2015 Elsevier.

Graphene and carbon nanotubes have excellent performance during severe plastic deformation, thus the composite integrating these carbon nanomaterials with the SMONs can achieve excellent sensing performance and mechanical flexibility. For
example, a flexible isopropanol sensor was fabricated using a mixture of WO$_3$$\cdot$0.33H$_2$O nano-needles and rGO on PET substrates (see Fig. 27a)\textsuperscript{404}. Compared with the sensor made on the pure WO$_3$$\cdot$0.33H$_2$O nano-needles, the 5%rGO/WO$_3$$\cdot$0.33H$_2$O based sensor showed a better selectivity and a superior response (4.96 to 100 ppm to isopropanol) (see Fig. 27b), with a good performance after repeated bending for many cycles. Similarly, SWNT-Fe$_2$O$_3$ composite films were prepared using CVD method and then transferred onto the flexible PP polymer substrate\textsuperscript{406}. Compared that fabricated using the single SWNTs, the flexible gas sensor of the SWNT-Fe$_2$O$_3$ composite film exhibited an improved response to H$_2$S at RT. Under repeated bending to large angles (such as 90$^\circ$ and 180$^\circ$) for 16 times as shown in Fig. 27c, the flexible sensor exhibited stable sensing response values to H$_2$S. For another example, hydrothermally synthesized WO$_3$ nanoparticles were mixed with MWCNTs (see Fig 27d), and then casted onto a PET substrate to fabricate a flexible NO$_2$ gas sensor\textsuperscript{416}. This sensors not only shows a good sensing performance, but also has an excellent mechanical flexibility (see Fig. 27e). There was no significant degradation of response values after bending/ relaxing for 10$^6$ cycles, demonstrating the excellent mechanical robustness of the MWCNTs/WO$_3$ composite layers on the flexible gas sensors (see Fig. 27f).

Cotton fabrics are also reported to be used as a good substrate for the flexible RT gas sensor, for example, a flexible NH$_3$ gas sensor was made by growing the nanostructured ZnO onto the cotton fabrics\textsuperscript{411}. Flexible nanowires of the SMONs can also be isostatically pressed into a thin paper, and then the nanowire paper is cut into small pieces to directly fabricate flexible gas sensor. Based on this idea, a-MoO$_3$ nanowires paper\textsuperscript{421} have been fabricated and a flexible gas sensor was made to detect hydrogen gas. The sensor shows fast response and recovery speeds (3.0 and 2.7 s toward 1.5% H$_2$), good selectivity, and high sensitivity at RT. Wei et al.\textsuperscript{422} also reported a flexible gas sensors based on cellulose/TiO$_2$/PANI composite nanofibers, which showed an excellent ammonia gas sensing performance at RT. Similarly, a stretchable ZnO nan accordion structures has also shown its good applications in flexible RT gas sensors\textsuperscript{423}.

In summary, the flexible RT gas sensors can be fabricated using the SMONs as the
sensing materials onto a mechanically flexible platform, and the sensors have demonstrated excellent mechanical robustness and can maintain good sensing performance at RT after bending/recovering many times. Furthermore, the composite of SMONs with graphene or CNT can achieve better mechanical robustness for the flexible gas sensor. However, so far, the sensing performance of the flexible RT gas sensors and reliability and stability have not achieved excellent performance as those of the rigid counterparts.

5. Conclusions and outlook

In this paper, we have summarized the recent progress on designs and mechanisms of RT gas sensors based on the different SMONs. Our emphasis has been on the critical review of different structures of SMONs-based gas sensors that may help the design of new devices. The key topics covered in this paper include: single phase n-type SMONs, single phase p-type SMONs, noble metal nanoparticles modified SMONs, metal ion modified SMONs, SMONs composites with multiple metal oxides, and the SMONs composites with carbon nanomaterials. The different nanostructures of these SMONs include nanoparticles, nanowires, nanofibers, nanorods, nanosheets, nanotubes etc. Sensing performance of these SMONs based RT sensors have been reviewed for detecting various toxic or flammable gases, such as hydrogen disulfide, nitrogen dioxide, ammonia, carbon monoxide and hydrogen, as well as organic gas of formaldehyde, acetone, methanol and ethanol, etc. In addition, the photoactivated RT gas sensors and flexible RT gas sensors based on SMONs are also summarized.

Availability of numerous surface chemisorbed oxygen species of O$_2^-$ at the RT was identified to be the key reason for the high sensitivity of these RT gas sensors. These oxygen species react with the target molecules to change the electronic resistance of the sensor. However, many RT H$_2$S sensors are exceptional as the sensing mechanism is dominant by the formation of metallic conducting metal sulfide.

Noble metal nanoparticles on the surface of SMONs can stimulate the adsorption of oxygen molecules to form oxygen ions by the reduction processes. These oxygen ions spill onto the surface of SMONs to improve the concentration of oxygen ions on the
surface of SMONs for sensing reaction. In addition, noble metal nanoparticles can accelerate the transfer of electrons to SMONs. Therefore, both the chemical sensitization and electronic sensitization enhance the sensitivity and speed of the SMONs-based sensors. Doping of metal ions in the SMONs can increase the number of active sites and defects on the surface of SMON nanocrystals, thus enhance the amount of oxygen species and increase the adsorbed gas molecules on the sensor surface. Heterojunctions can form at the interfaces of different metal oxides or at the interfaces between the SMONs and carbon nanomaterials. These can effectively accelerate the transformation of electrons and enhance oxygen adsorption, and are beneficial to improve the sensitivity and response rates in application of RT gas sensors. The sensing performance also depends significantly on the nanostructures of the SMONs. Large specific surfaces are beneficial to the formation of more oxygen species, and porous nanostructures facilitate the adsorption and desorption of target gases, thus achieving fast response and recovery.

Generally, the RT SMONs based gas sensors show high response values and low LODs, however, their response and recovery times could be too long. Modifications of the SMONs sensors using various methods can improve their sensing performance, which include using: the noble metal modified SMONs; the metal ion doped SMONs, the composite SMONs, and the composite with carbon nanomaterials. The key conclusions are summarized below:

(1) Surface modifications of the SMONs using noble metal nanoparticles can effectively enhance their sensitivity, response/recovery speeds, selectivity and LODs through both chemical sensitization and electronic sensitization.

(2) Metal ion doped SMONs have increased number of active sites and more defects on their surfaces, which can enhance the oxygen species for sensing reactions and improve the adsorption of gas molecules.

(3) SMON composites can form abundant oxygen vacancies on their surfaces, thus providing many active sites. Heterojunctions can be formed at the interfaces of different metal oxides, which can effectively accelerate the transformation of electrons between different particles, thus improving the response rates. The
composite SMONs often contain numerous mesopores which are beneficial to the adsorption and desorption of gas molecules. Hence, sensors based on the majority of reported composite oxides exhibit high response value and very fast response.

(4) Because of the high conductivity of carbon nanomaterials, the composites of SMONs combined with carbon nanomaterials can achieve fast response/recovery.

(5) The photo-generated electrons on the surfaces of SMON sensing materials can enhance the chemisorption of oxygen molecules to form more $O_2^-$, which can enhance the sensitivity and response/recovery speed of the SMONs.

(6) RT flexible gas sensors based on the sensing layer of the SMONs sensing materials have the excellent mechanical robustness and can maintain good sensing performance after repeated bending/recovering.

Although up there has been significant progress in developing novel SMONs for gas sensing at RT, there are still many challenges and problems towards achieving high response, fast response/recovery speed, good selectivity and long-term stability:

(1) One of the key challenges is the durability and long-term stability of the sensors for application in varying environmental conditions, such as different humidity levels and different temperatures, which could cause significant influences for the sensing properties of many RT gas sensors. This is especially important for RT NH$_3$ sensing, as high humidity seriously affects the sensitivity and the response time. Light exposure, especially ultraviolet lights and infrared, and even visible lights, all influence the response of the RT SMONs sensors. In the literature, the performance of sensors has been normally characterized based on experiments conducted in well-controlled laboratory environment. However, in a practical setting with variable environmental conditions, the sensing performance may be altered with light exposure. Therefore, the sensing properties under different environmental conditions should be systematically investigate in order to establish the relationship between environmental conditions and sensing properties, which are then used to correct the sensing results.

(2) Interfering gases often affect the sensing performance, resulting in a drastically reduced response. Lack of good selectivity is still the most serious problem
hindering the wide applications of these RT gas sensors. There are few reports of the specific gas sensors which only respond to a target gas but not all the other gases. Because the resistive gas sensors are relied on their changes of resistance upon adsorption of gas molecules, it can distinguish between the reducing gases and oxidizing gas based on the increase or decrease of resistance, however, it is difficult to discriminate a group of gases which can produce the similar changing trends of resistance values.

Therefore, selectivity is particularly important for multiple-agent gas sensors. To solve this problem, arrays of different sensing materials can be fabricated such that forming an array of gas sensors, which could obtain good selectivity by analyzing and comparing data from the different single sensors. For example, Zhang et al. reported a method to detect multiple VOCs using an array of gas sensors based on Ag doped LaFeO$_3$ (ALFO). The device was optimized for the detection of acetone, benzene, methanol and formaldehyde to monitor air quality. The selectivity of ALFO can be altered using a molecular imprinting technique towards specific targets. Responsivity values of individual sensing elements vary between 14 and 21 while the values to other VOCs are lower than 4. The response and recovery times are on the order of 10 s and 100 s levels. Flitti et al. reported a micromachined 4×4 array of sensors for multiple target detection. The sensing film for individual elements is based on SnO$_2$ and the elements are post-treated using metal catalysts of Pt, Pd, and Au and ion implanted using B, P, and H. The basic post-treatment methods are effective to selectively detect gases of CO, CH$_4$, Ethanol, CH$_4$-CO, Ethanol-CO, and Ethanol-CH$_4$ using an algorithm based on a vector angle similarity. Recognition accuracy higher than 95% is reported in this study. This method has been demonstrated being capable of forming 12,000 virtual sensors using dedicated temperature modulations. Sensing network will be the future trends.

(3) The sensing mechanism of the SMONs is mainly based on the interaction between the target gas molecules and chemisorbed oxygens species, such as O$_2^-$, O$^-$ and O$_2^{2-}$ ions. However, other oxygen groups such as OH$^-$ can also react with the target gas
molecules. More effective analysis and theory development of the surface groups is urgently needed to assess its effect on the sensing properties, and the surface modification methods should be developed to minimize this influence.

(4) Many gas sensing mechanisms of SMONs based materials with various sizes and morphologies have been presented to explain their sensing properties. However, it is not clearly elucidated why the same SMON based materials with similar sizes and morphologies show remarkably different sensing properties. Therefore, \textit{in situ} characterization techniques and theory development for the sensing mechanisms are necessary.

(5) Response times of many RT gas sensors is very long, which cannot meet the need for timely triggering of the alarm. Exploring novel SMONs based sensing materials for rapid response at RT is still necessary. 3-D nano-arrays of SMONs facilitate the gas diffusion, which might be promising to shorten the response time.

(6) Flexible wearable RT gas sensors are in a great demand due to their promising applications. The SMONs with a potential of higher carrier mobility and mechanical robustness, are one of the good candidates for making the stretchable and flexible gas sensors. For RT gas sensors, there is still challenges for their manufacturing technologies, and cracking and spalling problems of SMONs layers on the flexible substrates usually happen, which need to be solved to achieve reliable RT flexible gas sensors. Therefore, finding new low-cost SMONs based sensing materials with excellent sensing performance and mechanical robustness is still the major challenge.

\textbf{Conflicts of interest}

There are no conflicts to declare.

\textbf{Acknowledgements}

This work is supported by National Key Research and Development Program of China (Grant no. 2016YFB0402705), National Natural Science Foundation of China (NSFC, 21711530211, 61390502), the Foundation for Innovative Research Groups of the National Natural Science Foundation of China (Grant No.51521003) and by Self-
Planned Task (NO. SKLRS201607B) of State Key Laboratory of Robotics and System (HIT), Shenzhen Science & Technology Project (Grant no. JCYJ20170817100658231), UK Engineering Physics and Science Research Council (EPSRC EP/P018998/1 and EP/P026435/1) and Newton Mobility Grant (IE161019) through Royal Society and NFSC, as well as Royal academy of Engineering UK-Research Exchange with China and India.

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